

## Transformer Driver for Isolated Power Supplies

Check for Samples: [SN6501](#)

### FEATURES

- Push-Pull Driver for Small Transformers
- Single 3.3 V or 5 V Supply
- High Primary-side Current Drive:
  - 5 V Supply: 350 mA (max)
  - 3.3 V Supply: 150 mA (max)
- Low Ripple on Rectified Output Permits Small Output Capacitors
- Small 5-pin SOT23 Package

### APPLICATIONS

- Isolated Interface Power Supply for CAN, RS-485, RS-422, RS-232, SPI, I2C, Low-Power LAN
- Industrial Automation
- Process Control
- Medical Equipment

### DESCRIPTION

The SN6501 is a monolithic oscillator/power-driver, specifically designed for small form factor, isolated power supplies in isolated interface applications. It drives a low-profile, center-tapped transformer primary from a 3.3 V or 5 V DC power supply. The secondary can be wound to provide any isolated voltage based on transformer turns ratio.

The SN6501 consists of an oscillator followed by a gate drive circuit that provides the complementary output signals to drive the ground referenced N-channel power switches. The internal logic ensures break-before-make action between the two switches.

The SN6501 is available in a small SOT23-5 package, and is specified for operation at temperatures from  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ .

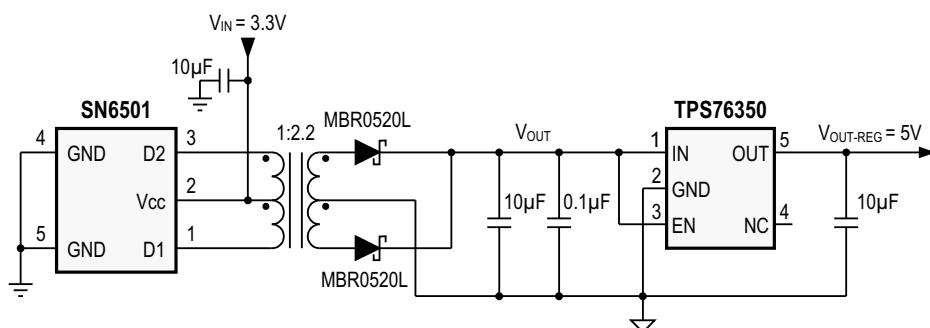


Figure 1. Typical Operating Circuit

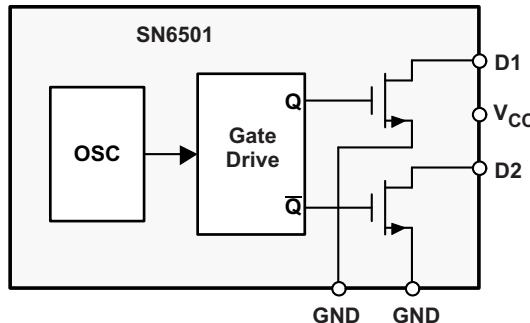


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

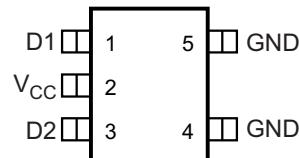


These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## FUNCTIONAL BLOCK DIAGRAM

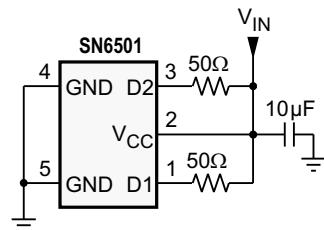


## PIN FUNCTIONS



PIN No.	NAME	DESCRIPTION
1	D1	Drain 1
2	V <sub>CC</sub>	Supply voltage
3	D2	Drain 2
4,5	GND	Ground

## TEST CIRCUIT



**Figure 2. Test Circuit for  $R_{ON}$ ,  $f_{SW}$ ,  $f_{St}$ ,  $t_{r-D}$ ,  $t_{f-D}$ ,  $t_{BBM}$**

## ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

			VALUES	
V <sub>CC</sub> Supply voltage			–0.3 V to +6 V	
V <sub>D1</sub> , V <sub>D2</sub> Output switch voltage			14 V	
I <sub>D1P</sub> , I <sub>D2P</sub> Peak output switch current			500 mA	
P <sub>TOT</sub> Continuous power dissipation			250 mW	
ESD	Human Body Model	ESDA/JEDEC JS-001-2012	All Pins	±4 kV
	Charged Device Model	JEDEC JESD22-C101E		±1.5 kV
	Machine Model	JEDEC JESD22-A115-A		±200 V
T <sub>STG</sub> Storage temperature range				–65°C to 150°C
T <sub>J</sub> Junction temperature				170°C

(1) Stresses beyond those listed under ABSOLUTE MAXIMUM RATINGS cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under RECOMMENDED OPERATING CONDITIONS is not implied. Exposure to absolute-maximum-rated conditions for extended periods affects device reliability.

## THERMAL INFORMATION

THERMAL METRIC <sup>(1)</sup>		SN6501	UNITS
		DBV 5-PINS	
θ <sub>JA</sub>	Junction-to-ambient thermal resistance	208.3	°C/W
θ <sub>JCTop</sub>	Junction-to-case (top) thermal resistance	87.1	
θ <sub>JB</sub>	Junction-to-board thermal resistance	40.4	
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	5.2	
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	39.7	
θ <sub>JCbot</sub>	Junction-to-case (bottom) thermal resistance	N/A	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

## RECOMMENDED OPERATING CONDITIONS

		MIN	TYP	MAX	UNIT
V <sub>CC</sub>	Supply voltage	3	5.5		V
V <sub>D1</sub> , V <sub>D2</sub>	Output switch voltage	V <sub>CC</sub> = 5 V ± 10%,	When connected to Transformer with primary winding Center-tapped		V
		V <sub>CC</sub> = 3.3 V ± 10%	0	11	
I <sub>D1</sub> , I <sub>D2</sub>	D1 and D2 output switch current – Primary-side	V <sub>CC</sub> = 5 V ± 10%	V <sub>D1</sub> , V <sub>D2</sub> Swing ≥ 3.8 V, see <a href="#">Figure 58</a> for typical characteristics		mA
		V <sub>CC</sub> = 3.3 V ± 10%	V <sub>D1</sub> , V <sub>D2</sub> Swing ≥ 2.5 V, see <a href="#">Figure 57</a> for typical characteristics		
T <sub>A</sub>	Ambient temperature		–40	125	°C

## ELECTRICAL CHARACTERISTICS

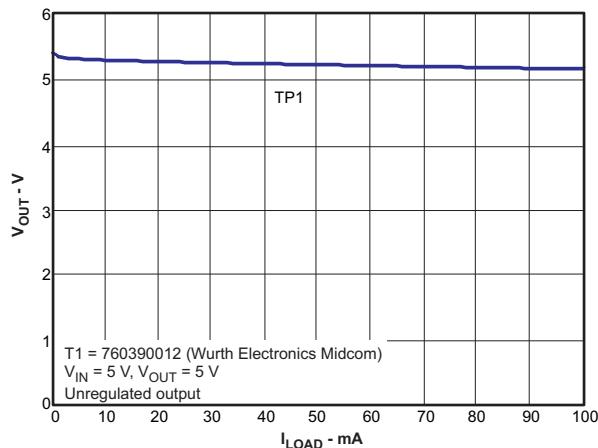
Over full-range of recommended operating conditions, unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
R <sub>ON</sub>	Switch-on resistance	V <sub>CC</sub> = 3.3 V ± 10%, See <a href="#">Figure 2</a>		1	3	Ω
		V <sub>CC</sub> = 5 V ± 10%, See <a href="#">Figure 2</a>		0.6	2	
I <sub>CC</sub>	Average supply current <sup>(1)</sup>	V <sub>CC</sub> = 3.3 V ± 10%, no load		150	400	uA
		V <sub>CC</sub> = 5 V ± 10%, no load		300	700	
f <sub>ST</sub>	Startup frequency	V <sub>CC</sub> = 2.4 V, See <a href="#">Figure 2</a>		300		kHz
f <sub>SW</sub>	D1, D2 Switching frequency	V <sub>CC</sub> = 3.3 V ± 10%, See <a href="#">Figure 2</a>	250	360	550	kHz
		V <sub>CC</sub> = 5 V ± 10%, See <a href="#">Figure 2</a>	300	410	620	
t <sub>r-D</sub>	D1, D2 output rise time	V <sub>CC</sub> = 3.3 V ± 10%, See <a href="#">Figure 2</a>		70		ns
		V <sub>CC</sub> = 5 V ± 10%, See <a href="#">Figure 2</a>		80		
t <sub>f-D</sub>	D1, D2 output fall time	V <sub>CC</sub> = 3.3 V ± 10%, See <a href="#">Figure 2</a>		110		ns
		V <sub>CC</sub> = 5 V ± 10%, See <a href="#">Figure 2</a>		60		
t <sub>BBM</sub>	Break-before-make time	V <sub>CC</sub> = 3.3 V ± 10%, See <a href="#">Figure 2</a>		150		ns
		V <sub>CC</sub> = 5 V ± 10%, See <a href="#">Figure 2</a>		50		

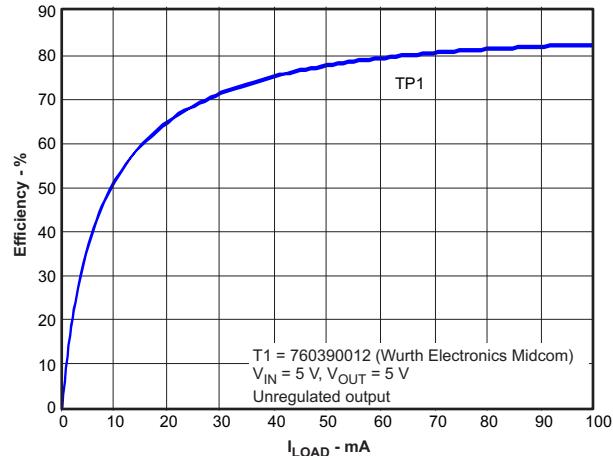
(1) Average supply current is the current used by SN6501 only. It does not include load current.

## TYPICAL OPERATING CHARACTERISTICS

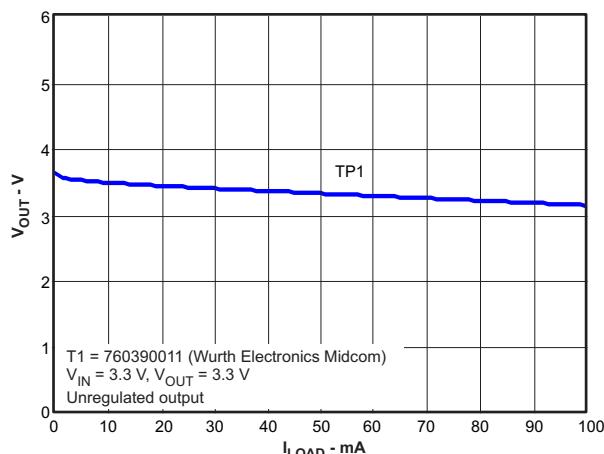
Typical Curves in [Figure 3](#) through [Figure 14](#) are measured with Circuit in [Figure 67](#) at TP1; whereas, Typical Curves in [Figure 15](#) through [Figure 54](#) are measured with Circuit in [Figure 68](#) at TP1 and TP2 ( $T_A = 25^\circ\text{C}$  unless otherwise noted). See [Table 2](#) and [Table 3](#) for Transformer Specifications.



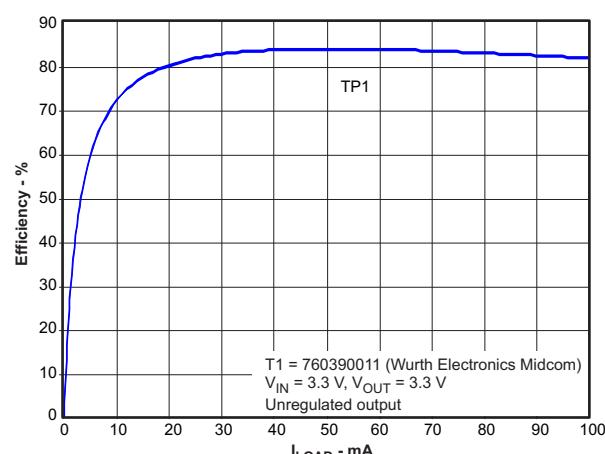
**Figure 3. Output Voltage vs. Load Current**



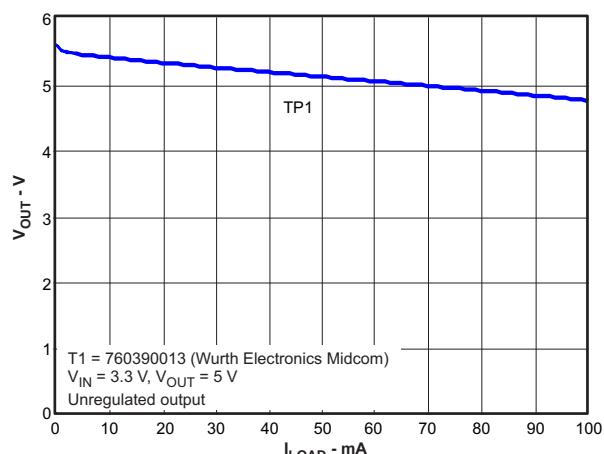
**Figure 4. Efficiency vs Load Current**



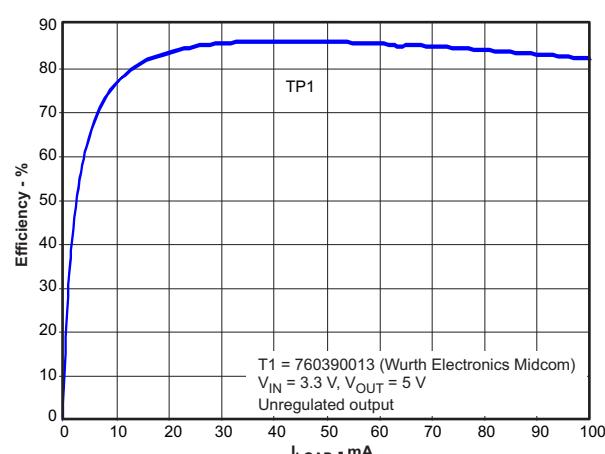
**Figure 5. Output Voltage vs Load Current**



**Figure 6. Efficiency vs Load Current**



**Figure 7. Output Voltage vs Load Current**



**Figure 8. Efficiency vs Load Current**

### TYPICAL OPERATING CHARACTERISTICS (continued)

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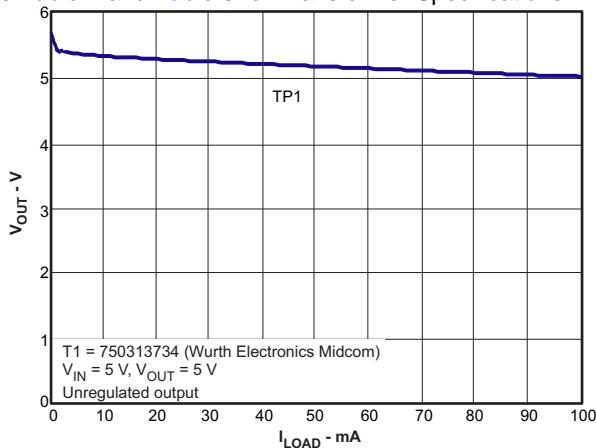


Figure 9. Output Voltage vs Load Current

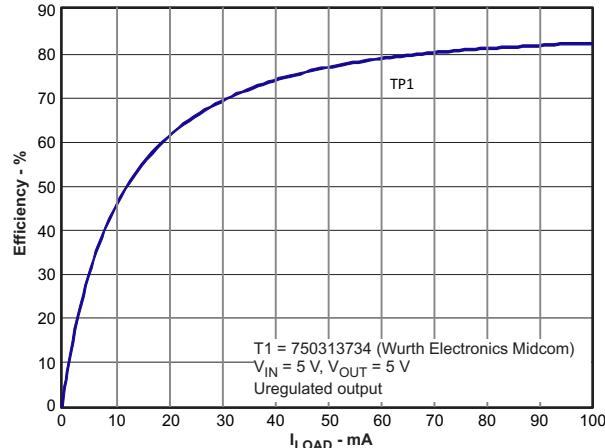


Figure 10. Efficiency vs Load Current

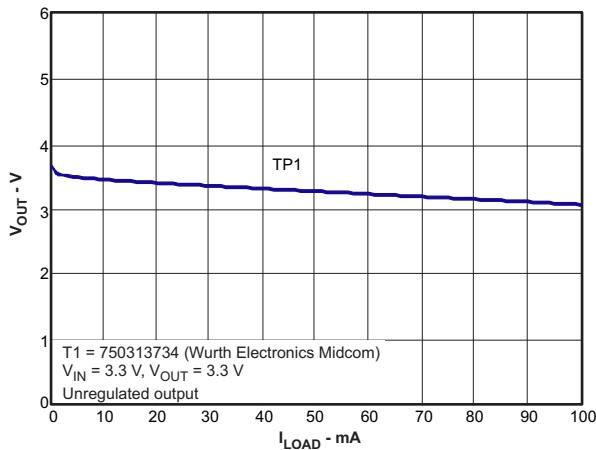


Figure 11. Output Voltage vs Load Current

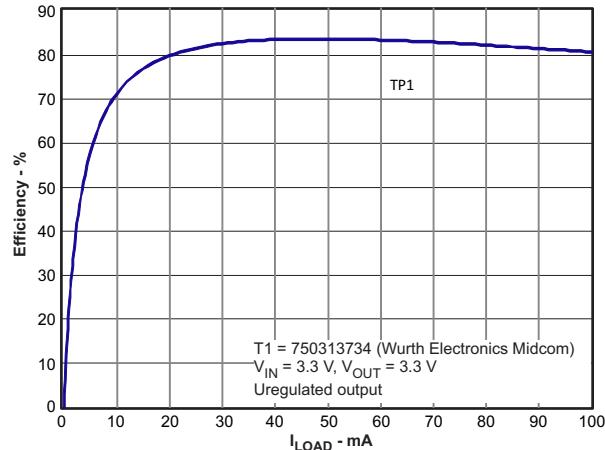


Figure 12. Efficiency vs Load Current

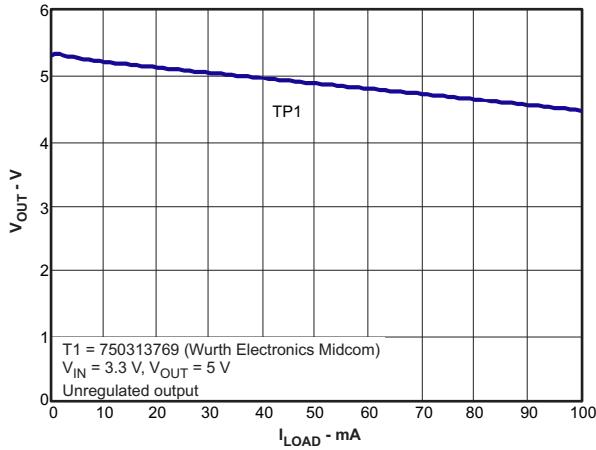


Figure 13. Output Voltage vs Load Current

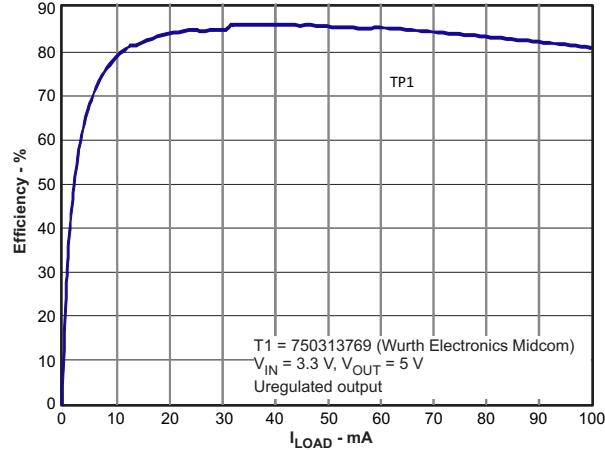
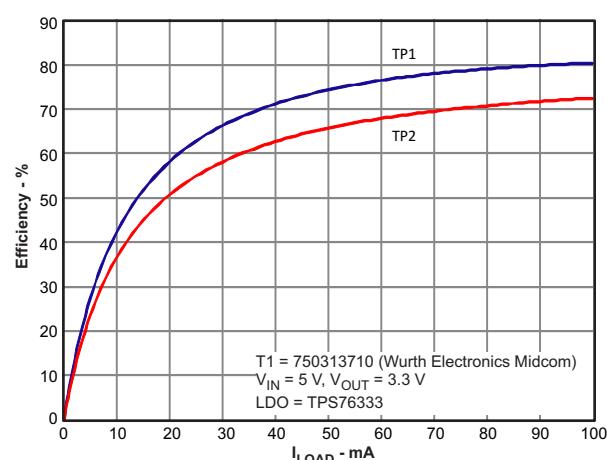
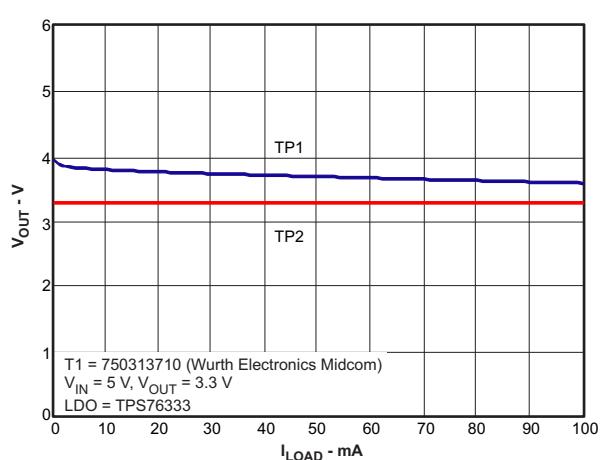
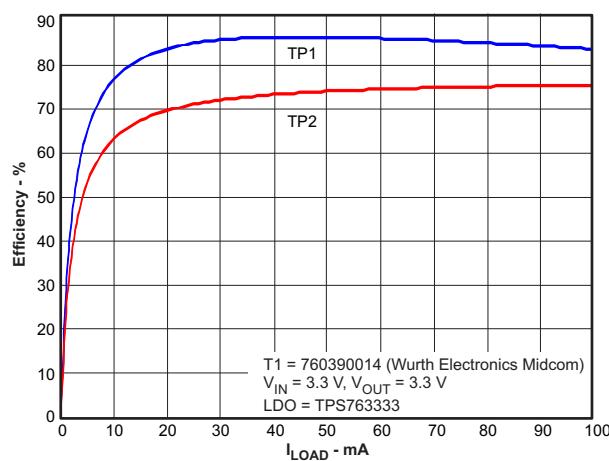
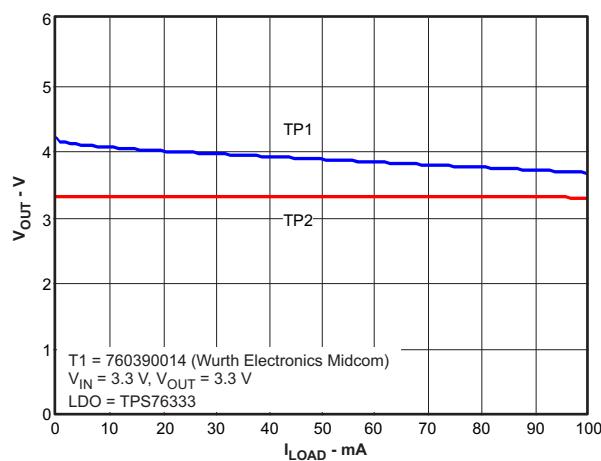
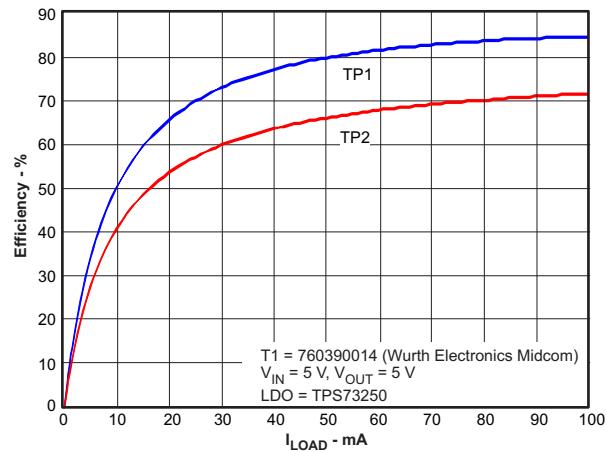
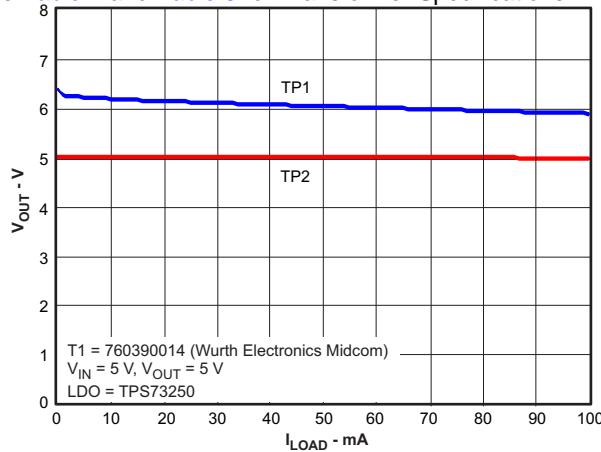


Figure 14. Efficiency vs Load Current

### TYPICAL OPERATING CHARACTERISTICS (continued)

Typical Curves in [Figure 3](#) through [Figure 14](#) are measured with Circuit in [Figure 67](#) at TP1; whereas, Typical Curves in [Figure 15](#) through [Figure 54](#) are measured with Circuit in [Figure 68](#) at TP1 and TP2 ( $T_A = 25^\circ\text{C}$  unless otherwise noted).

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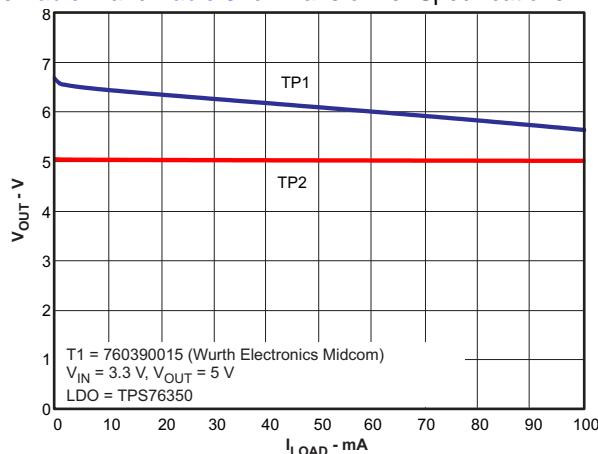


Figure 21. Output Voltage vs Load Current

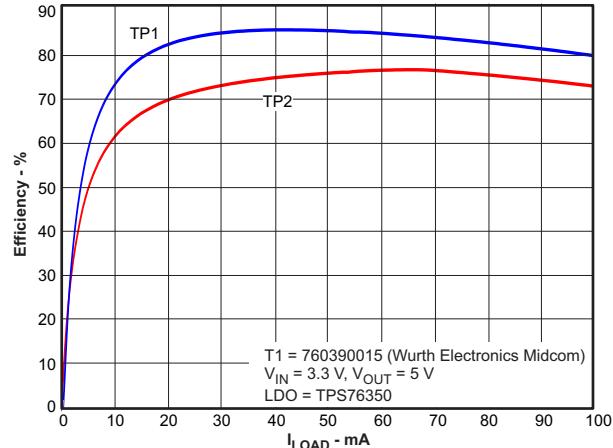


Figure 22. Efficiency vs Load Current

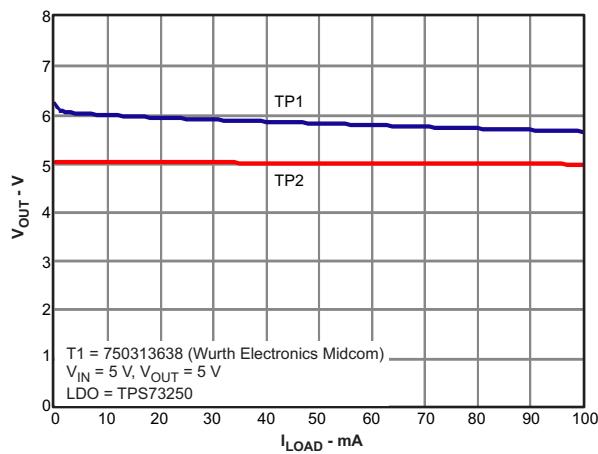


Figure 23. Output Voltage vs Load Current

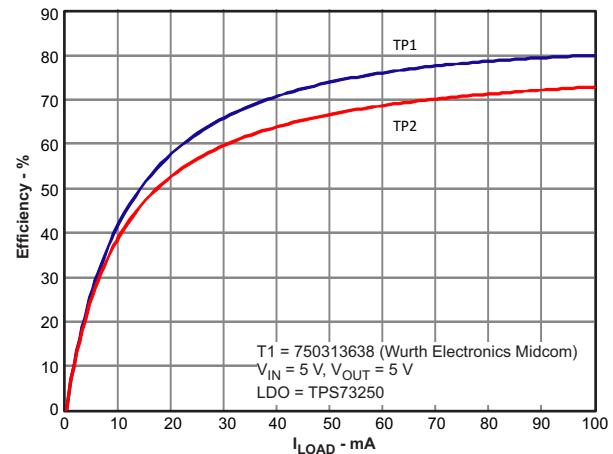


Figure 24. Efficiency vs Load Current

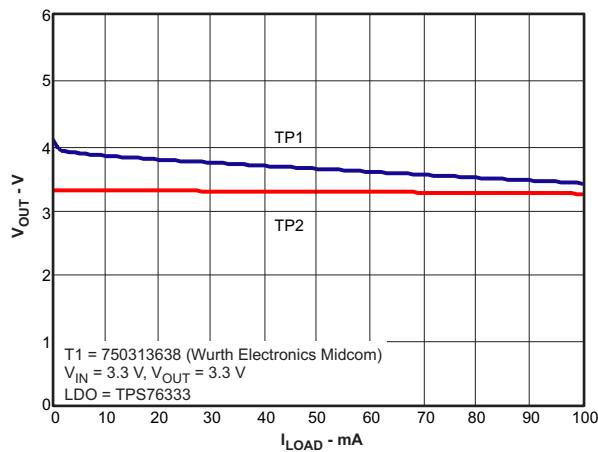


Figure 25. Output Voltage vs Load Current

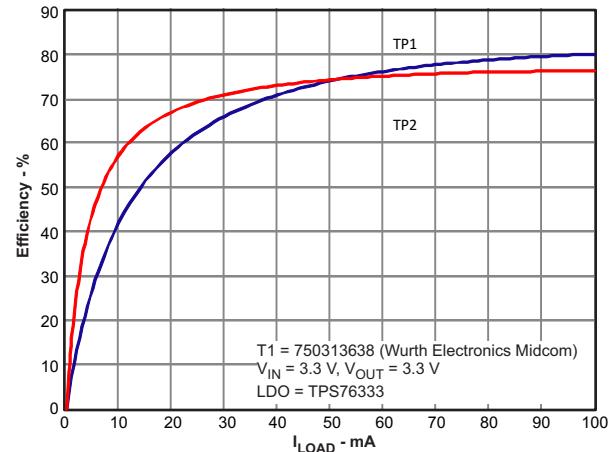
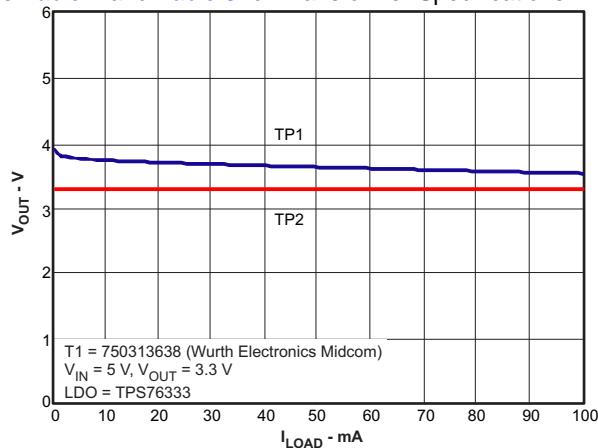


Figure 26. Efficiency vs Load Current

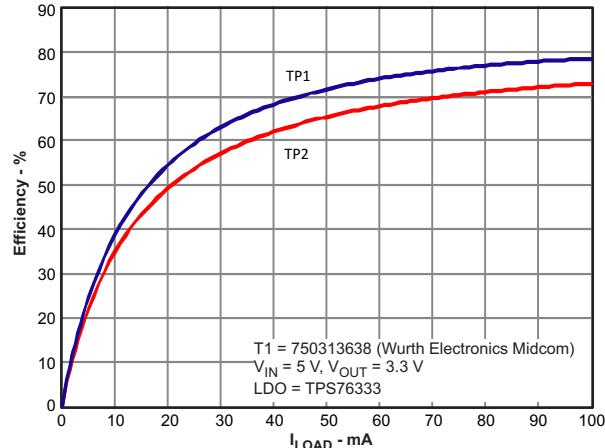
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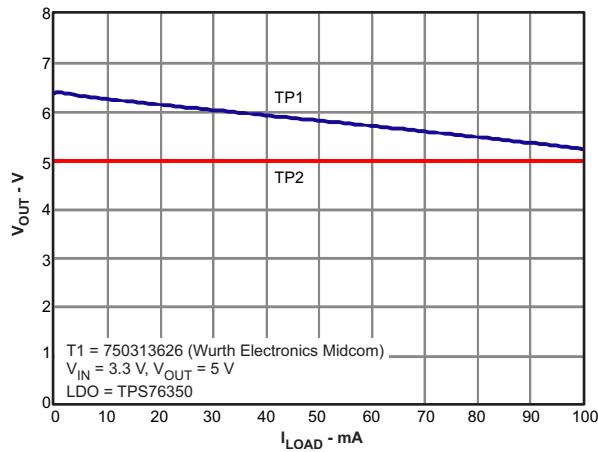
See [Table 2](#) and [Table 3](#) for Transformer Specifications.



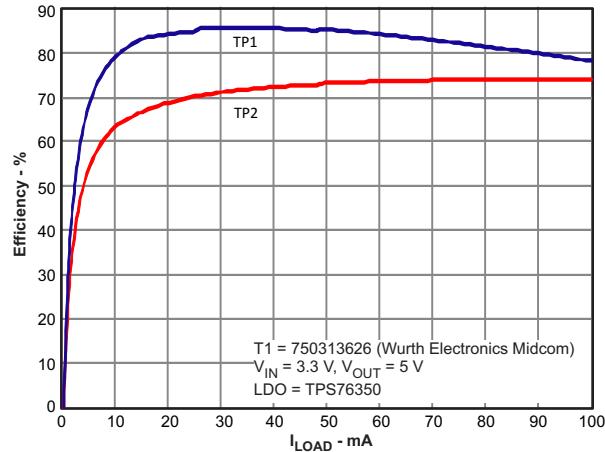
**Figure 27. Output Voltage vs Load Current**



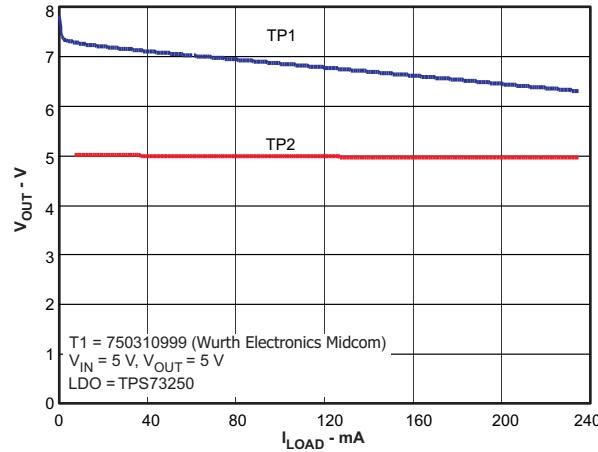
**Figure 28. Efficiency vs Load Current**



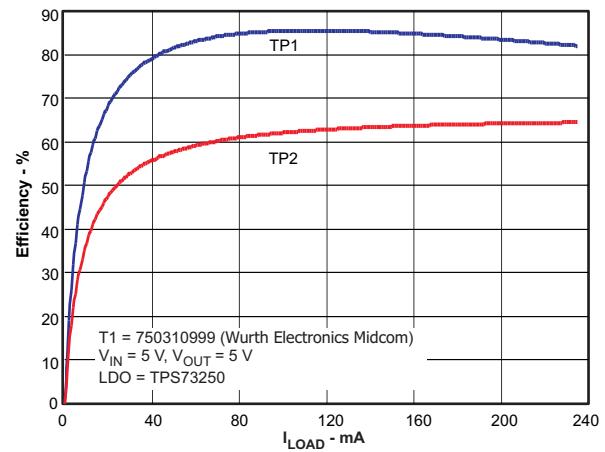
**Figure 29. Output Voltage vs Load Current**



**Figure 30. Efficiency vs Load Current**



**Figure 31. Output Voltage vs Load Current**

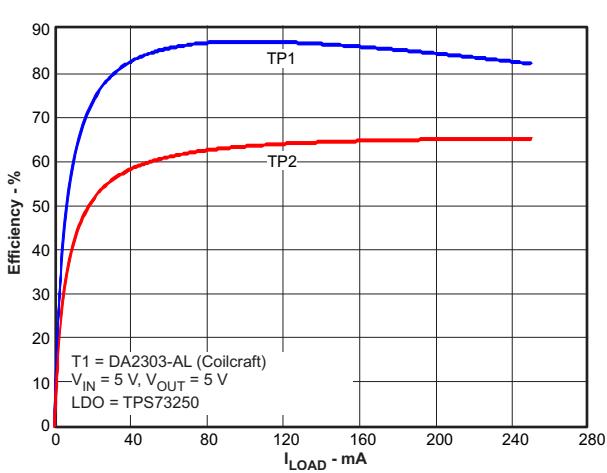
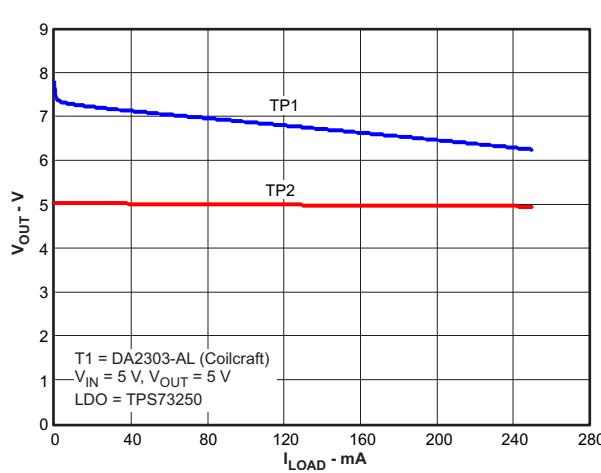
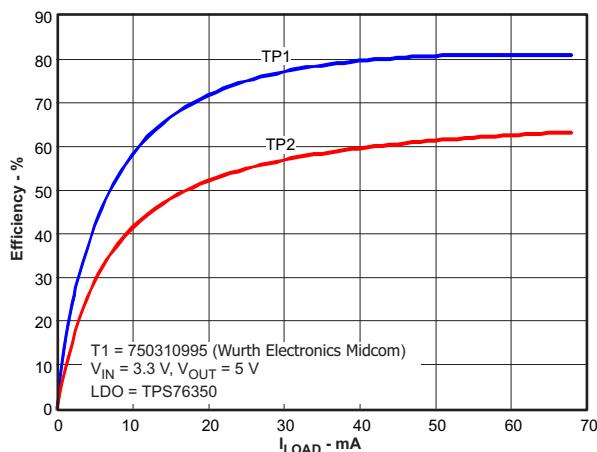
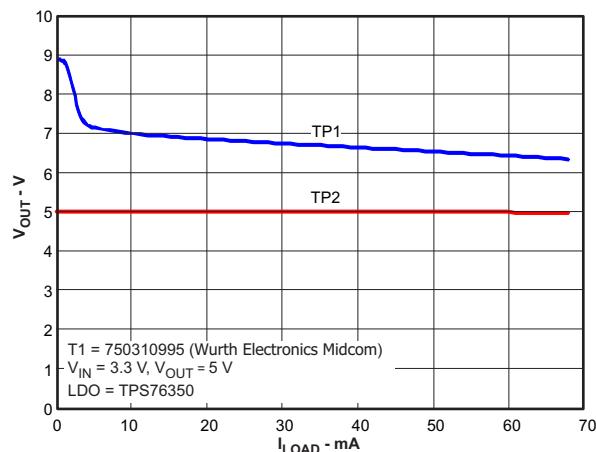
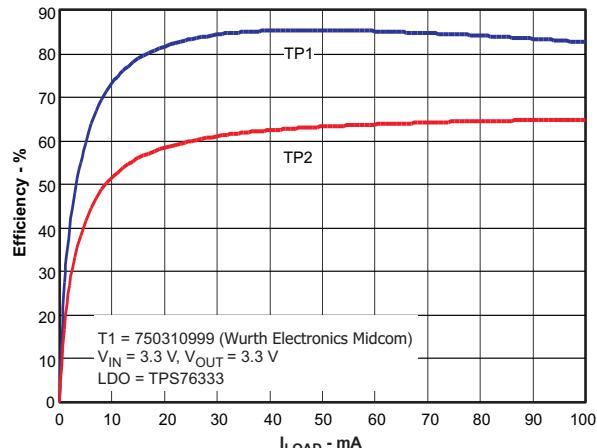
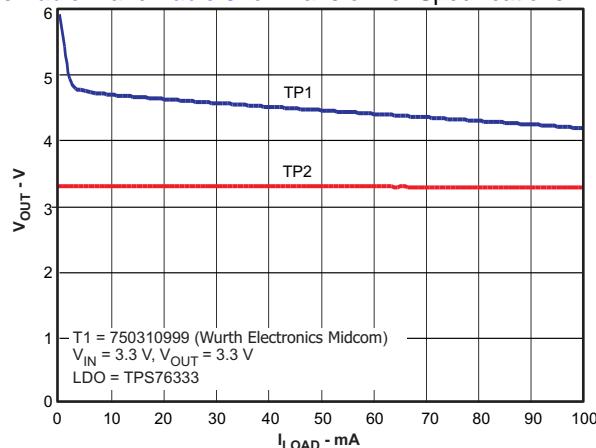


**Figure 32. Efficiency vs Load Current**

### TYPICAL OPERATING CHARACTERISTICS (continued)

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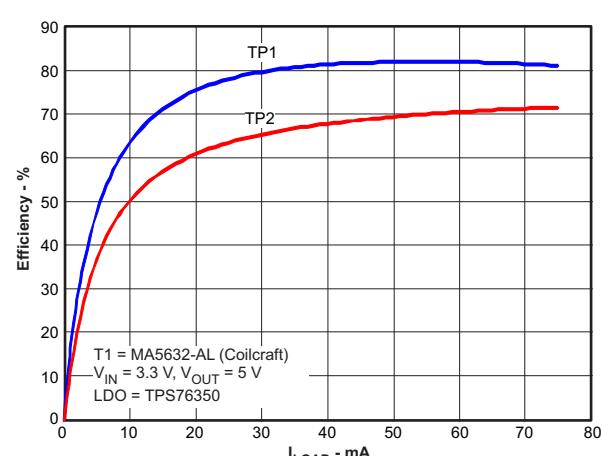
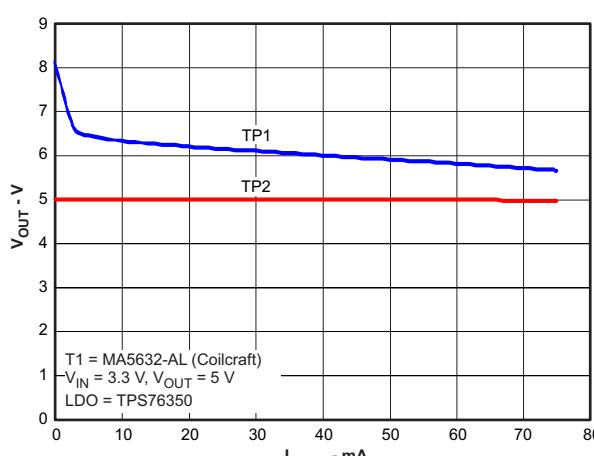
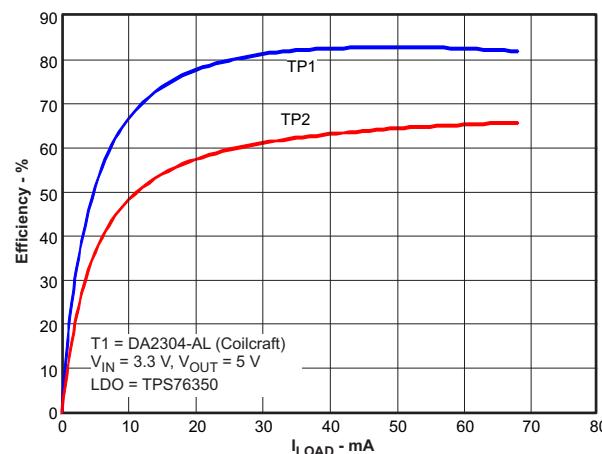
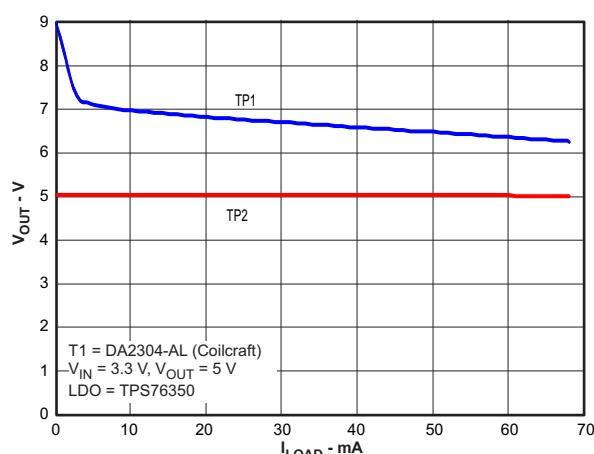
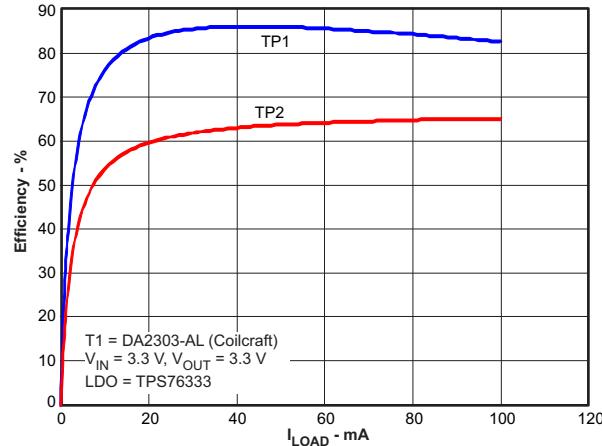
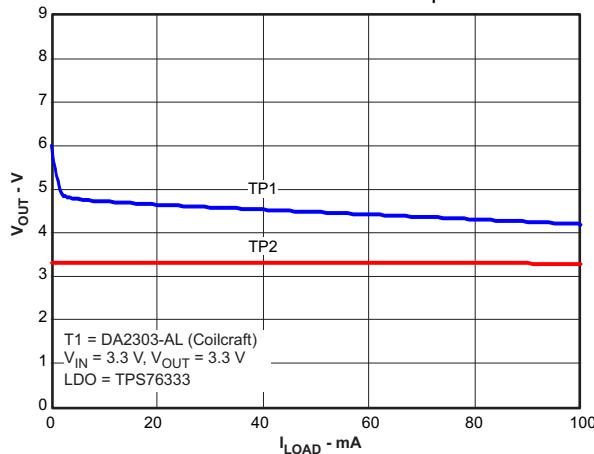
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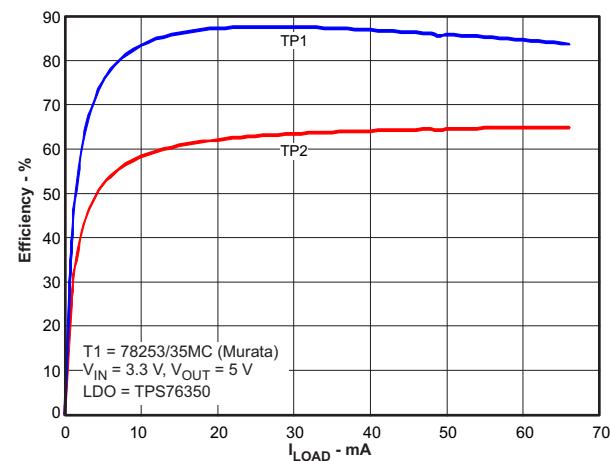
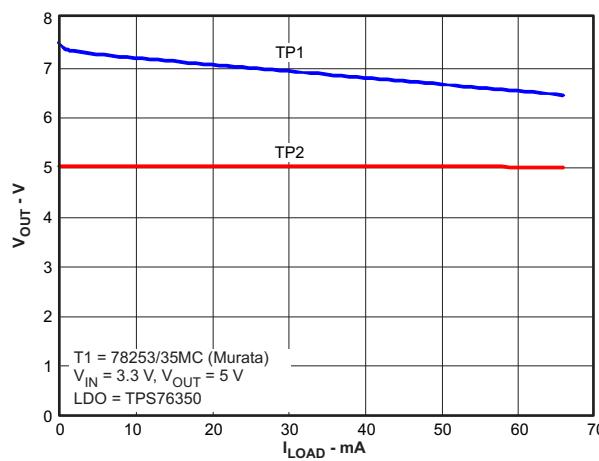
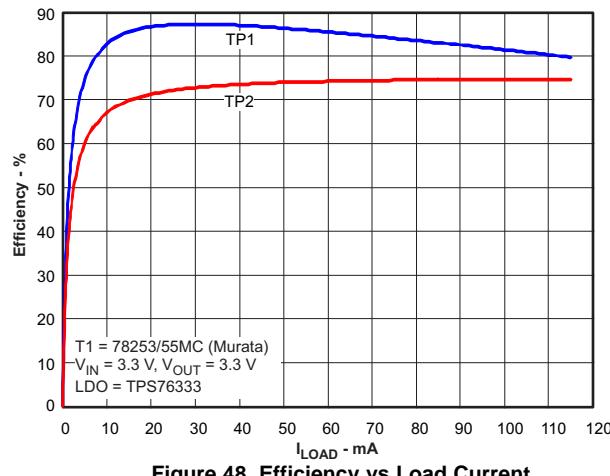
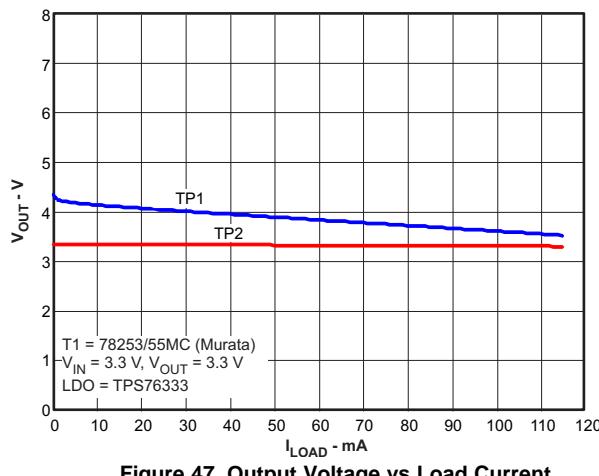
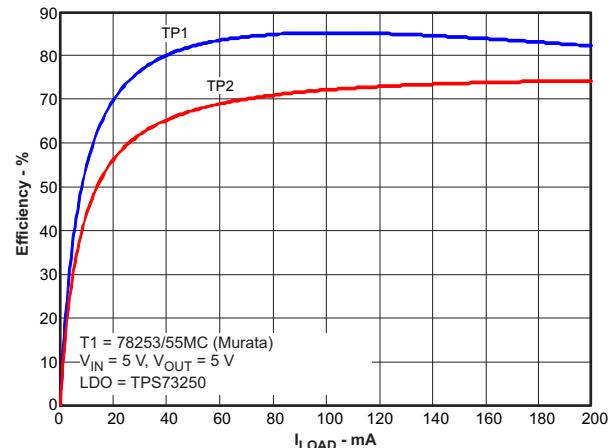
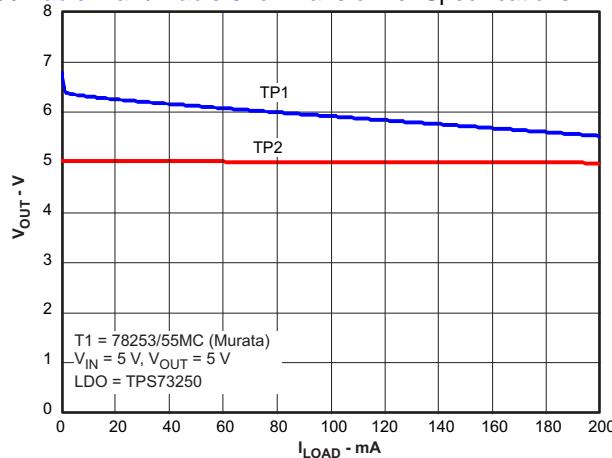
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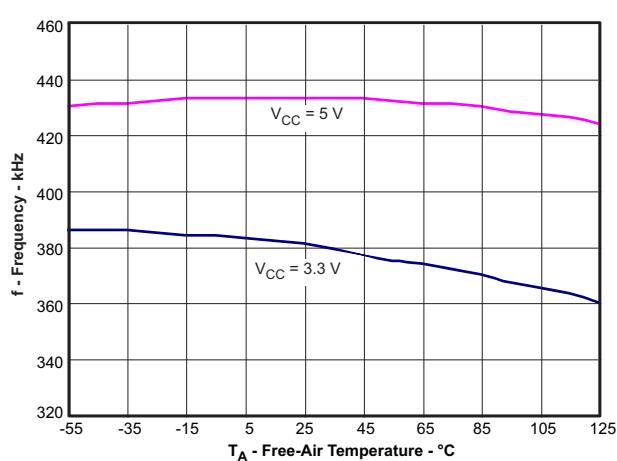
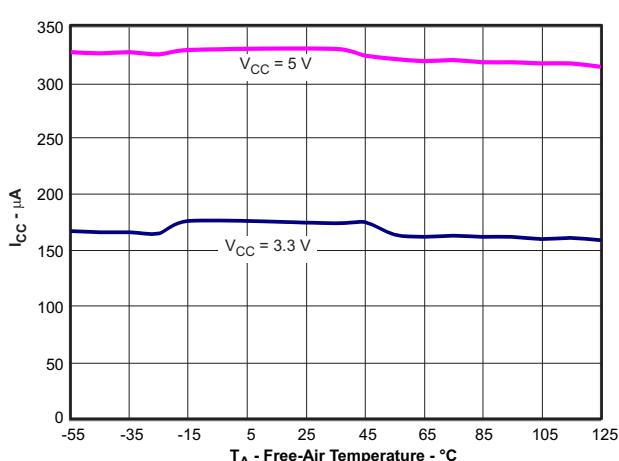
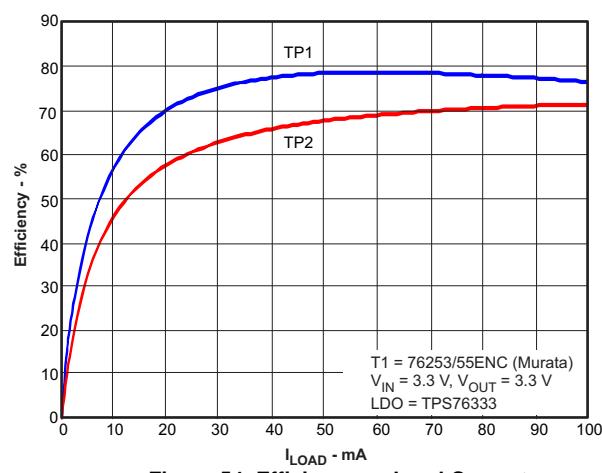
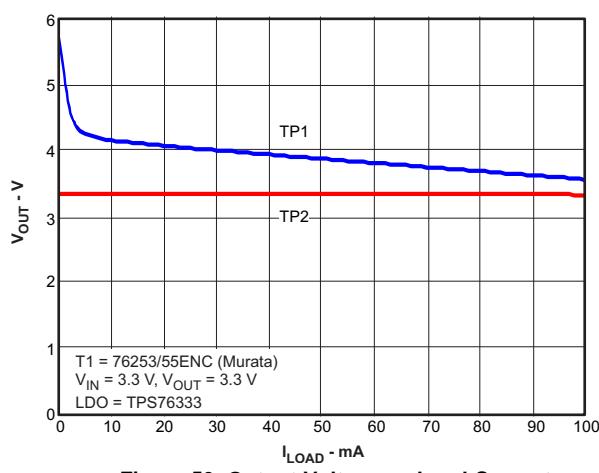
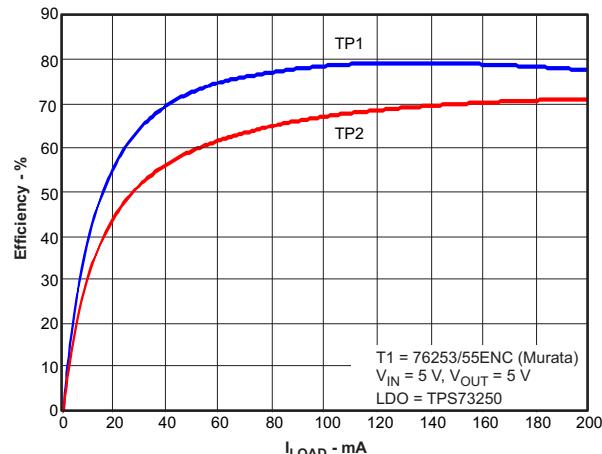
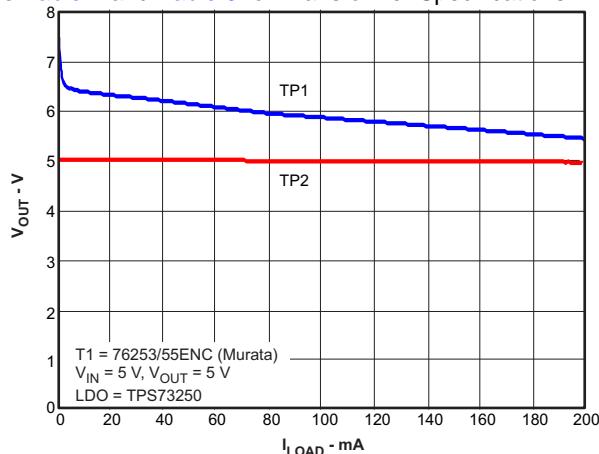
See Table 2 and Table 3 for Transformer Specifications.



### TYPICAL OPERATING CHARACTERISTICS (continued)

Typical Curves in Figure 3 through Figure 14 are measured with Circuit in Figure 67 at TP1; whereas, Typical Curves in Figure 15 through Figure 54 are measured with Circuit in Figure 68 at TP1 and TP2 ( $T_A = 25^\circ\text{C}$  unless otherwise noted).

See Table 2 and Table 3 for Transformer Specifications.



### TYPICAL OPERATING CHARACTERISTICS (continued)

Typical Curves in Figure 3 through Figure 14 are measured with Circuit in Figure 67 at TP1; whereas, Typical Curves in Figure 15 through Figure 54 are measured with Circuit in Figure 68 at TP1 and TP2 ( $T_A = 25^\circ\text{C}$  unless otherwise noted).

See Table 2 and Table 3 for Transformer Specifications.

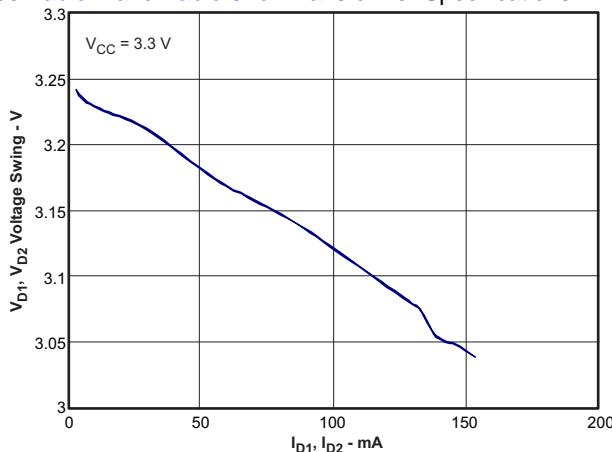


Figure 57. D1, D2 Primary-side Output Switch Voltage Swing vs Current

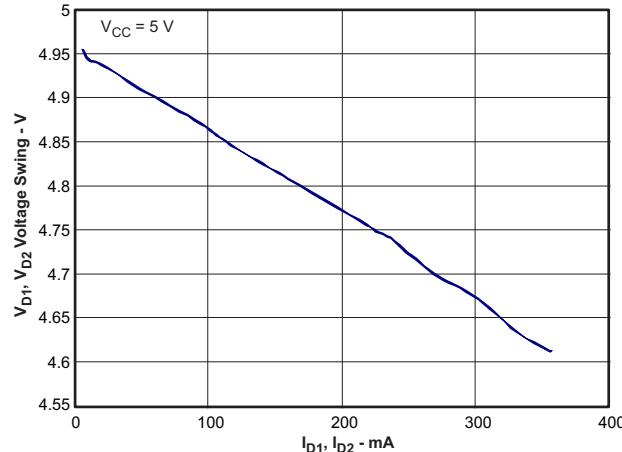


Figure 58. D1, D2 Primary-side Output Switch Voltage Swing vs Current

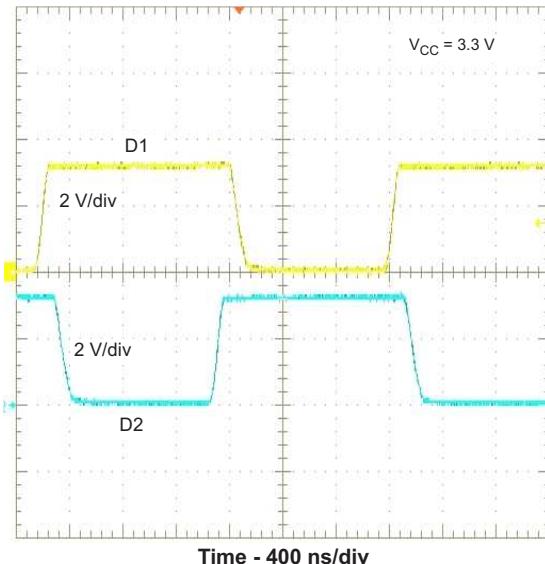


Figure 59. D1, D2 Switching Waveforms

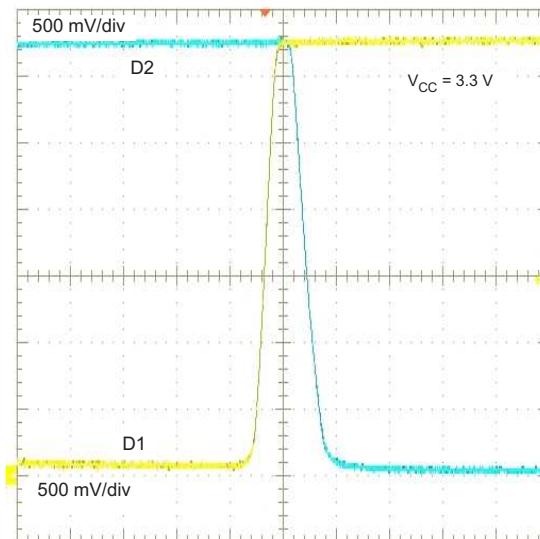
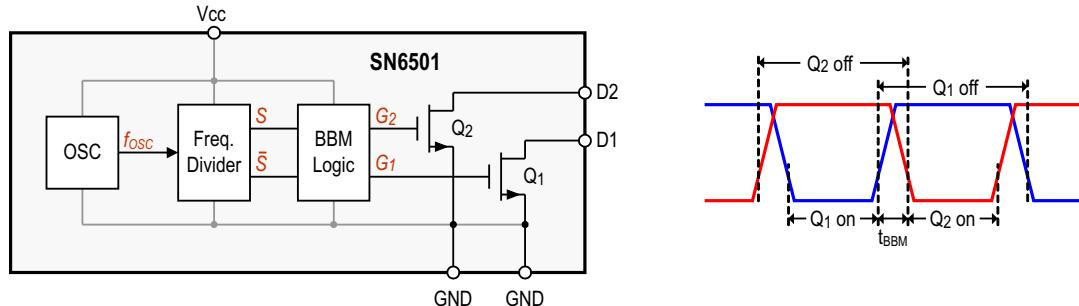


Figure 60. D1, D2 Break-Before-Make Waveform

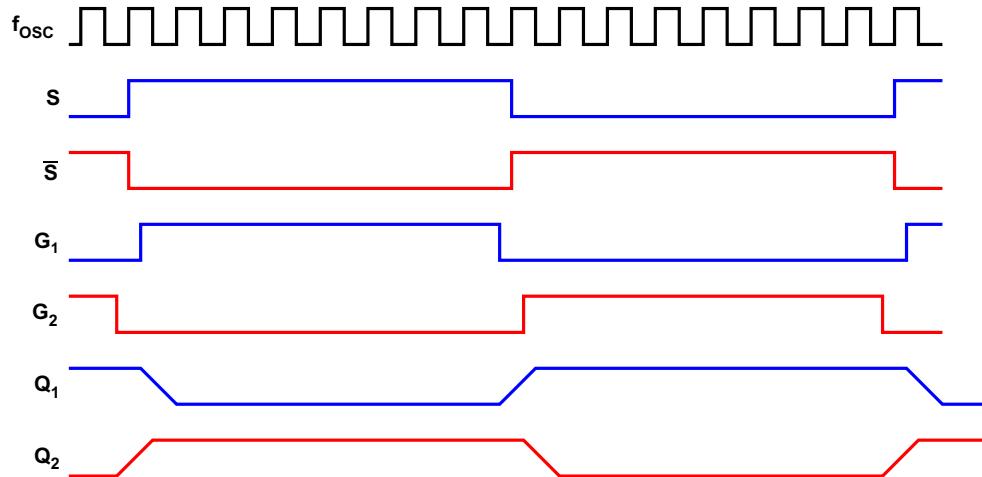
## APPLICATION INFORMATION

The SN6501 is a transformer driver designed for low-cost, small form-factor, isolated DC-DC converters utilizing the push-pull topology. The device includes an oscillator that feeds a gate-drive circuit. The gate-drive, comprising a frequency divider and a break-before-make (BBM) logic, provides two complementary output signals which alternately turn the two output transistors on and off.



**Figure 61. SN6501 Block Diagram and Output Timing with Break-Before-Make Action**

The output frequency of the oscillator is divided down by an asynchronous divider that provides two complementary output signals, S and  $\bar{S}$ , with a 50% duty cycle. A subsequent break-before-make logic inserts a dead-time between the high-pulses of the two signals. The resulting output signals,  $G_1$  and  $G_2$ , present the gate-drive signals for the output transistors  $Q_1$  and  $Q_2$ . As shown in Figure 62, before either one of the gates can assume logic high, there must be a short time period during which both signals are low and both transistors are high-impedance. This short period, known as break-before-make time, is required to avoid shorting out both ends of the primary.



**Figure 62. Detailed Output Signal Waveforms**

## PUSH-PULL CONVERTER

Push-pull converters require transformers with center-taps to transfer power from the primary to the secondary (see Figure 63).

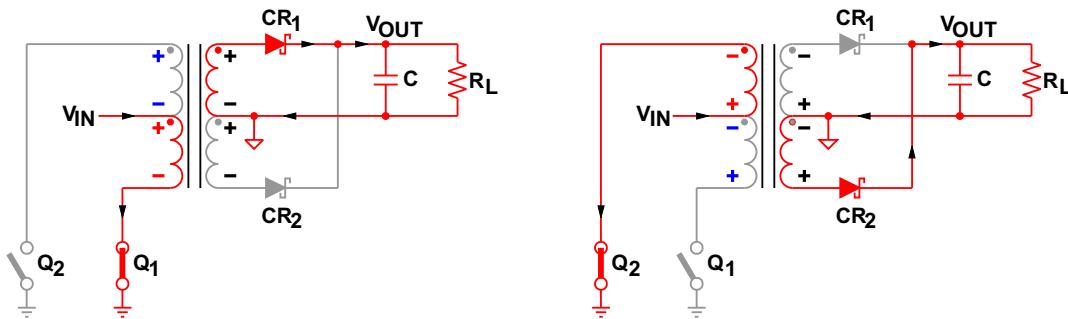


Figure 63. Switching Cycles of a Push-Pull Converter

When Q1 conducts, VIN drives a current through the lower half of the primary to ground, thus creating a negative voltage potential at the lower primary end with regards to the VIN potential at the center-tap.

At the same time the voltage across the upper half of the primary is such that the upper primary end is positive with regards to the center-tap in order to maintain the previously established current flow through Q2, which now has turned high-impedance. The two voltage sources, each of which equaling VIN, appear in series and cause a voltage potential at the open end of the primary of  $2 \times V_{IN}$  with regards to ground.

Per dot convention the same voltage polarities that occur at the primary also occur at the secondary. The positive potential of the upper secondary end therefore forward biases diode CR1. The secondary current starting from the upper secondary end flows through CR1, charges capacitor C, and returns through the load impedance RL back to the center-tap.

When Q2 conducts, Q1 goes high-impedance and the voltage polarities at the primary and secondary reverse. Now the lower end of the primary presents the open end with a  $2 \times V_{IN}$  potential against ground. In this case CR2 is forward biased while CR1 is reverse biased and current flows from the lower secondary end through CR2, charging the capacitor and returning through the load to the center-tap.

## CORE MAGNETIZATION

Figure 64 shows the ideal magnetizing curve for a push-pull converter with B as the magnetic flux density and H as the magnetic field strength. When Q1 conducts the magnetic flux is pushed from A to A', and when Q2 conducts the flux is pulled back from A' to A. The difference in flux and thus in flux density is proportional to the product of the primary voltage, Vp, and the time, t<sub>ON</sub>, it is applied to the primary:  $B \approx V_p \times t_{ON}$ .

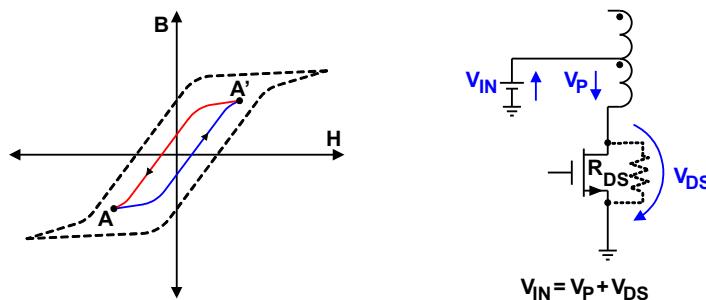


Figure 64. Core Magnetization and Self-Regulation Through Positive Temperature Coefficient of  $R_{DS(on)}$

This volt-seconds (V-t) product is important as it determines the core magnetization during each switching cycle. If the V-t products of both phases are not identical, an imbalance in flux density swing results with an offset from the origin of the B-H curve. If balance is not restored, the offset increases with each following cycle and the transformer slowly creeps toward the saturation region.

Fortunately, due to the positive temperature coefficient of a MOSFET's on-resistance, the output FETs of the SN6501 have a self-correcting effect on V-t imbalance. In the case of a slightly longer on-time, the prolonged current flow through a FET gradually heats the transistor which leads to an increase in  $R_{DS-on}$ . The higher resistance then causes the drain-source voltage,  $V_{DS}$ , to rise. Because the voltage at the primary is the difference between the constant input voltage,  $V_{IN}$ , and the voltage drop across the MOSFET,  $V_P = V_{IN} - V_{DS}$ ,  $V_P$  is gradually reduced and V-t balance restored.

## CONVERTER DESIGN

The following recommendations on components selection focus on the design of an efficient push-pull converter with high current drive capability. Contrary to popular belief, the output voltage of the unregulated converter output drops significantly over a wide range in load current. The characteristic curve in [Figure 41](#) for example shows that the difference between  $V_{OUT}$  at minimum load and  $V_{OUT}$  at maximum load exceeds a transceiver's supply range. Therefore, in order to provide a stable, load independent supply while maintaining maximum possible efficiency the implementation of a low dropout regulator (LDO) is strongly advised.

The final converter circuit is shown in [Figure 68](#). The measured  $V_{OUT}$  and efficiency characteristics for the regulated and unregulated outputs are shown in [Figure 37](#) to [Figure 36](#).

## SN6501 DRIVE CAPABILITY

The SN6501 transformer driver is designed for low-power push-pull converters with input and output voltages in the range of 3 V to 5.5 V. While converter designs with higher output voltages are possible, care must be taken that higher turns ratios don't lead to primary currents that exceed the SN6501 specified current limits.

## LDO SELECTION

The minimum requirements for a suitable low dropout regulator are:

- Its current drive capability should slightly exceed the specified load current of the application to prevent the LDO from dropping out of regulation. Therefore for a load current of 100 mA, choose a 100 mA to 150 mA LDO. While regulators with higher drive capabilities are acceptable, they also usually possess higher dropout voltages that will reduce overall converter efficiency.
- The internal dropout voltage,  $V_{DO}$ , at the specified load current should be as low as possible to maintain efficiency. For a low-cost 150 mA LDO, a  $V_{DO}$  of 150 mV at 100 mA is common. Be aware however, that this lower value is usually specified at room temperature and can increase by a factor of 2 over temperature, which in turn will raise the required minimum input voltage.
- The required minimum input voltage preventing the regulator from dropping out of line regulation is given with:

$$V_{I-min} = V_{DO-max} + V_{O-max}$$

This means in order to determine  $V_I$  for worst-case condition, the user must take the maximum values for  $V_{DO}$  and  $V_O$  specified in the LDO data sheet for rated output current (i.e., 100 mA) and add them together. Also specify that the output voltage of the push-pull rectifier at the specified load current is equal or higher than  $V_{I-min}$ . If it is not, the LDO will lose line-regulation and any variations at the input will pass straight through to the output. Hence below  $V_{I-min}$  the output voltage will follow the input and the regulator behaves like a simple conductor.

- The maximum regulator input voltage must be higher than the rectifier output under no-load. Under this condition there is no secondary current reflected back to the primary, thus making the voltage drop across  $R_{DS-on}$  negligible and allowing the entire converter input voltage to drop across the primary. At this point the secondary reaches its maximum voltage of

$$V_{S-max} = V_{IN-max} \times n$$

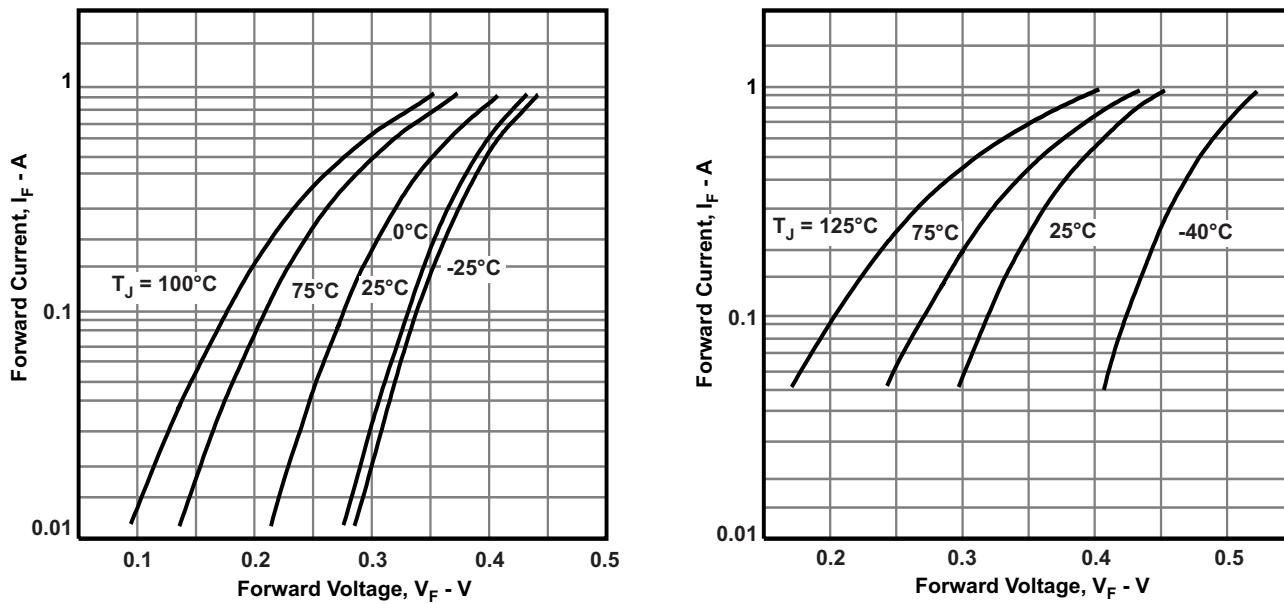
with  $V_{IN-max}$  as the maximum converter input voltage and  $n$  as the transformer turns ratio. Thus to prevent the LDO from damage the maximum regulator input voltage must be higher than  $V_{S-max}$ . [Table 1](#) lists the maximum secondary voltages for various turns ratios commonly applied in push-pull converters with 100 mA output drive.

**Table 1. Required maximum LDO Input Voltages for Various Push-pull Configurations**

PUSH-PULL CONVERTER				LDO
CONFIGURATION	$V_{IN\text{-max}}$ [V]	URNS-RATIO	$V_{S\text{-max}}$ [V]	$V_{I\text{-max}}$ [V]
3.3 $V_{IN}$ to 3.3 $V_{OUT}$	3.6	1.5 ± 3%	5.6	6 to 10
3.3 $V_{IN}$ to 5 $V_{OUT}$	3.6	2.2 ± 3%	8.2	10
5 $V_{IN}$ to 5 $V_{OUT}$	5.5	1.5 ± 3%	8.5	10

## DIODE SELECTION

A rectifier diode should always possess low-forward voltage to provide as much voltage to the converter output as possible. When used in high-frequency switching applications, such as the SN6501 however, the diode must also possess a short recovery time. Schottky diodes meet both requirements and are therefore strongly recommended in push-pull converter designs. An excellent choice for low-volt applications is the MBR0520L with a typical forward voltage of 275 mV at 100 mA forward current. For higher output voltages such as ±10 V and above use the MBR0530 which provides a higher DC blocking voltage of 30 V.



**Figure 65. Diode Forward Characteristics for MBR0520L (left) and MBR0530 (right)**

## CAPACITOR SELECTION

The capacitors in the converter circuit in Figure 68 are multi-layer ceramic chip (MLCC) capacitors.

As with all high speed CMOS ICs, the SN6501 requires a bypass capacitor in the range of 10 nF to 100 nF.

The input bulk capacitor at the center-tap of the primary supports large currents into the primary during the fast switching transients. For minimum ripple make this capacitor 10  $\mu\text{F}$  to 22  $\mu\text{F}$ . In a 2-layer PCB design with a dedicated ground plane, place this capacitor close to the primary center-tap to minimize trace inductance. In a 4-layer board design with low-inductance reference planes for ground and  $V_{IN}$ , the capacitor can be placed at the supply entrance of the board. To ensure low-inductance paths use two vias in parallel for each connection to a reference plane or to the primary center-tap.

The bulk capacitor at the rectifier output smoothes the output voltage. Make this capacitor 10  $\mu\text{F}$  to 22  $\mu\text{F}$ .

The small capacitor at the regulator input is not necessarily required. However, good analog design practice suggests, using a small value of 47 nF to 100 nF improves the regulator's transient response and noise rejection.

The LDO output capacitor buffers the regulated output for the subsequent isolator and transceiver circuitry. The choice of output capacitor depends on the LDO stability requirements specified in the data sheet. However, in most cases, a low-ESR ceramic capacitor in the range of 4.7  $\mu\text{F}$  to 10  $\mu\text{F}$  will satisfy these requirements.

## TRANSFORMER SELECTION

### V-t Product Calculation

To prevent a transformer from saturation its V-t product must be greater than the maximum V-t product applied by the SN6501. The maximum voltage delivered by the SN6501 is the nominal converter input plus 10%. The maximum time this voltage is applied to the primary is half the period of the lowest frequency at the specified input voltage. Therefore, the transformer's minimum V-t product is determined through:

$$Vt_{\min} \geq V_{IN\text{-max}} \times \frac{T_{\max}}{2} = \frac{V_{IN\text{-max}}}{2 \times f_{\min}} \quad (1)$$

Inserting the numeric values from the data sheet into the equation above yields the minimum V-t products of

$$Vt_{\min} \geq \frac{3.6 \text{ V}}{2 \times 250 \text{ kHz}} = 7.2 \text{ V}\mu\text{s} \quad \text{for 3.3 V, and}$$

$$Vt_{\min} \geq \frac{5.5 \text{ V}}{2 \times 300 \text{ kHz}} = 9.1 \text{ V}\mu\text{s} \quad \text{for 5 V applications.} \quad (2)$$

Common V-t values for low-power center-tapped transformers range from 22 V $\mu$ s to 150 V $\mu$ s with typical footprints of 10 mm x 12 mm. However, transformers specifically designed for PCMCIA applications provide as little as 11 V $\mu$ s and come with a significantly reduced footprint of 6 mm x 6 mm only.

While Vt-wise all of these transformers can be driven by the SN6501, other important factors such as isolation voltage, transformer wattage, and turns ratio must be considered before making the final decision.

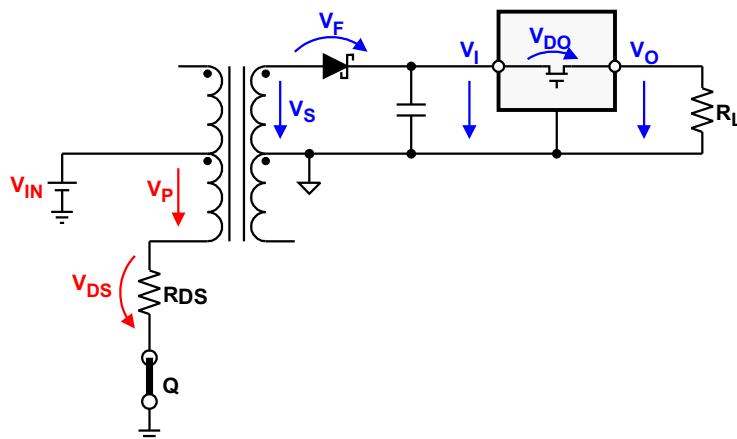
### Turns Ratio Estimate

Assume the rectifier diodes and linear regulator has been selected. Also, it has been determined that the transformer chosen must have a V-t product of at least 11 V $\mu$ s. However, before searching the manufacturer websites for a suitable transformer, the user still needs to know its minimum turns ratio that allows the push-pull converter to operate flawlessly over the specified current and temperature range. This minimum transformation ratio is expressed through the ratio of minimum secondary to minimum primary voltage multiplied by a correction factor that takes the transformer's typical efficiency of 97% into account:

$$V_{P\text{-min}} = V_{IN\text{-min}} - V_{DS\text{-max}} \quad (3)$$

$V_{S\text{-min}}$  must be large enough to allow for a maximum voltage drop,  $V_{F\text{-max}}$ , across the rectifier diode and still provide sufficient input voltage for the regulator to remain in regulation. From the LDO SELECTION section, this minimum input voltage is known and by adding  $V_{F\text{-max}}$  gives the minimum secondary voltage with:

$$V_{S\text{-min}} = V_{F\text{-max}} + V_{DO\text{-max}} + V_{O\text{-max}} \quad (4)$$



**Figure 66. Establishing the Required Minimum Turns Ratio Through  $n_{\min} = 1.031 \times V_{S\text{-min}} / V_{P\text{-min}}$**

Then calculating the available minimum primary voltage,  $V_{P\text{-min}}$ , involves subtracting the maximum possible drain-source voltage of the SN6501,  $V_{DS\text{-max}}$ , from the minimum converter input voltage  $V_{IN\text{-min}}$ :

$$V_{P\text{-min}} = V_{IN\text{-min}} - V_{DS\text{-max}} \quad (5)$$

$V_{DS\text{-max}}$  however, is the product of the maximum  $R_{DS(on)}$  and  $I_D$  values for a given supply specified in the SN6501 data sheet:

$$V_{DS\text{-max}} = R_{DS\text{-max}} \times I_{D\text{max}} \quad (6)$$

Then inserting [Equation 6](#) into [Equation 5](#) yields:

$$V_{P\text{-min}} = V_{IN\text{-min}} - R_{DS\text{-max}} \times I_{D\text{max}} \quad (7)$$

and inserting [Equation 7](#) and [Equation 4](#) into [Equation 3](#) provides the minimum turns ration with:

$$n_{\text{min}} = 1.031 \times \frac{V_{F\text{-max}} + V_{DO\text{-max}} + V_{O\text{-max}}}{V_{IN\text{-min}} - R_{DS\text{-max}} \times I_{D\text{max}}} \quad (8)$$

### Example:

For a 3.3  $V_{IN}$  to 5  $V_{OUT}$  converter using the rectifier diode MBR0520L and the 5 V LDO TPS76350, the data sheet values taken for a load current of 100 mA and a maximum temperature of 85°C are  $V_{F\text{-max}} = 0.2$  V,  $V_{DO\text{-max}} = 0.2$  V, and  $V_{O\text{-max}} = 5.175$  V.

Then assuming that the converter input voltage is taken from a 3.3 V controller supply with a maximum  $\pm 2\%$  accuracy makes  $V_{IN\text{-min}} = 3.234$  V. Finally the maximum values for drain-source resistance and drain current at 3.3 V are taken from the SN6501 data sheet with  $R_{DS\text{-max}} = 3 \Omega$  and  $I_{D\text{max}} = 150$  mA.

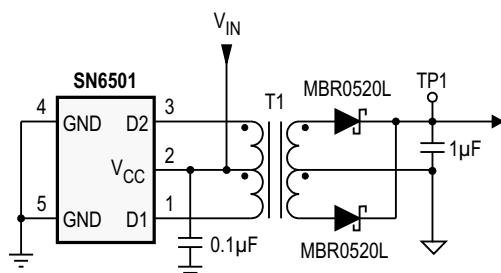
Inserting the values above into [Equation 8](#) yields a minimum turns ratio of:

$$n_{\text{min}} = 1.031 \times \frac{0.2V + 0.2V + 5.175V}{3.234V - 3\Omega \times 150mA} = 2 \quad (9)$$

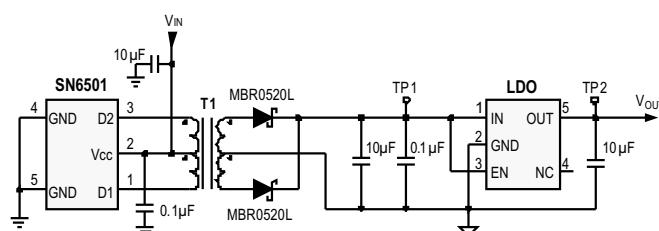
Most commercially available transformers for 3-to-5 V push-pull converters offer turns ratios between 2.0 and 2.3 with a common tolerance of  $\pm 3\%$ .

### Recommended Transformers

Depending on the application, use the minimum configuration in [Figure 67](#) or standard configuration in [Figure 68](#).



**Figure 67. Unregulated Output for Low-Current Loads with Wide Supply Range**



**Figure 68. Regulated Output for Stable Supplies and High Current Loads**

The Wurth Electronics Midcom isolation transformers in Table 2 are optimized designs for the SN6501, providing high efficiency and small form factor at low-cost.

The 1:1.1 and 1:1.7 turns-ratios are designed for logic applications with wide supply rails and low load currents. These applications operate without LDO, thus achieving further cost-reduction.

**Table 2. Recommended Isolation Transformers Optimized for SN6501**

Turns Ratio	V x T (V $\mu$ s)	Isolation (V <sub>RMS</sub> )	Dimensions (mm)	Application	LDO	Figures	Order No.	Manufacturer	
1:1.1	11	2500	6.73 x 10.05 x 4.19	5V → 5V	No	<a href="#">Figure 3</a> <a href="#">Figure 4</a>	760390012	Wurth Electronics Midcom	
1:1.1	7	2500	6.73 x 10.05 x 4.19	3.3V → 3.3V	No	<a href="#">Figure 5</a> <a href="#">Figure 6</a>	760390011		
1:1.7	11	2500	6.73 x 10.05 x 4.19	3.3V → 5V	No	<a href="#">Figure 7</a> <a href="#">Figure 8</a>	760390013		
1:1.1	11	5000	9.14 x 12.7 x 7.37	5V → 5V 3.3V → 3.3V	No	<a href="#">Figure 9</a> <a href="#">Figure 10</a> <a href="#">Figure 11</a> <a href="#">Figure 12</a>	750313734		
1:1.7	11	5000	9.14 x 12.7 x 7.37	3.3V → 5V	No	<a href="#">Figure 13</a> <a href="#">Figure 14</a>	750313769		
1:1.3	11	2500	6.73 x 10.05 x 4.19	5V → 5V 3.3V → 3.3V	Yes	<a href="#">Figure 15</a> <a href="#">Figure 16</a> <a href="#">Figure 17</a> <a href="#">Figure 18</a>	760390014		
1:23:1	11	2500	6.73 x 10.05 x 4.19	5V → 3.3V	Yes	<a href="#">Figure 19</a> <a href="#">Figure 20</a>	750313710		
1:2.0	11	2500	6.73 x 10.05 x 4.19	3.3V → 5V	Yes	<a href="#">Figure 21</a> <a href="#">Figure 22</a>	760390015		
1:1.3	11	5000	9.14 x 12.7 x 7.37	5V → 5V 3.3V → 3.3V	Yes	<a href="#">Figure 23</a> <a href="#">Figure 24</a> <a href="#">Figure 25</a> <a href="#">Figure 26</a> <a href="#">Figure 27</a> <a href="#">Figure 28</a>	750313638		
1.3:1				5V → 3.3V					
1:2	11	5000	9.14 x 12.7 x 7.37	3.3V → 5V	Yes	<a href="#">Figure 29</a> <a href="#">Figure 30</a>	750313626		

Other isolation transformers that have been tested with SN6501 are listed in [Table 3](#).

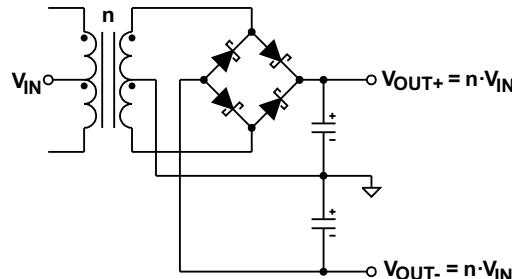
**Table 3. Standard Isolation Transformers Tested With SN6501**

Turns Ratio	V x T (V $\mu$ s)	Isolation (V) <sup>(1)</sup>	Dimensions (mm)	Application	LDO	Figures	Order No.	Manufacturer
1:1.5	11	2500	10 x 12.07 x 5.97	5V → 5V 3.3V → 3.3V	Yes	<a href="#">Figure 31</a> <a href="#">Figure 32</a> <a href="#">Figure 33</a> <a href="#">Figure 34</a>	750310999	Wurth Electronics Midcom
1:2.2	11	2500	10 x 12.07 x 5.97	3.3V → 5V	Yes	<a href="#">Figure 35</a> <a href="#">Figure 36</a>	750310995	
1:1.5	34.4	2500	10 x 12.7 x 5.97	5V → 5V 3.3V → 3.3V	Yes	<a href="#">Figure 37</a> <a href="#">Figure 38</a> <a href="#">Figure 39</a> <a href="#">Figure 40</a>	DA2303-AL	Coilcraft
1:2.2	21.5	2500	10 x 12.7 x 5.97	3.3V → 5V	Yes	<a href="#">Figure 41</a> <a href="#">Figure 42</a>	DA2304-AL	
1:2.0	10.2	2500	10 x 12.7 x 5.97	3.3V → 5V	Yes	<a href="#">Figure 43</a> <a href="#">Figure 44</a>	MA5632-AL	
1:1.31	50	1500	9 x 12.7 x 6.35	5V → 5V 3.3V → 3.3V	Yes	<a href="#">Figure 45</a> <a href="#">Figure 46</a> <a href="#">Figure 47</a> <a href="#">Figure 48</a>	78253/55MC	Murata
1:2.27	35	1500	9 x 12.7 x 6.35	3.3V → 5V	Yes	<a href="#">Figure 49</a> <a href="#">Figure 50</a>	78253/35MC	
1:1.33	50	6000	15 x 15.0 x 12.5	5V → 5V 3.3V → 3.3V	Yes	<a href="#">Figure 51</a> <a href="#">Figure 52</a> <a href="#">Figure 53</a> <a href="#">Figure 54</a>	76253/55ENC	

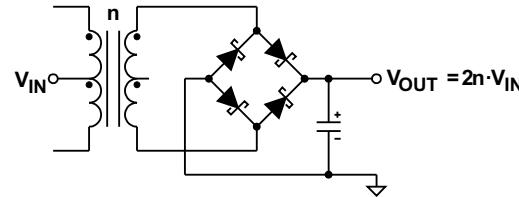
(1) Wurth Electronics Midcom and Coilcraft Transformer Isolation ratings are specified in V<sub>RMS</sub> while Murata Transformers ratings are given in V<sub>DC</sub>.

## HIGHER OUTPUT VOLTAGE DESIGNS

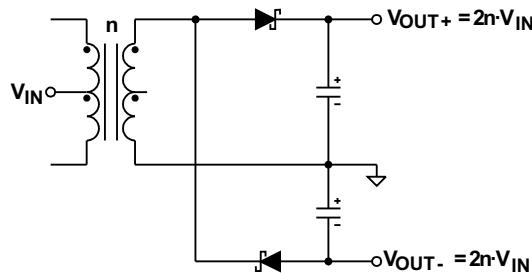
The SN6501 can drive push-pull converters that provide high output voltages of up to 30 V, or bipolar outputs of up to  $\pm 15$  V. Using commercially available center-tapped transformers, with their rather low turns ratios of 0.8 to 5, requires different rectifier topologies to achieve high output voltages. Figure 69 to Figure 72 show some of these topologies together with their respective open-circuit output voltages.



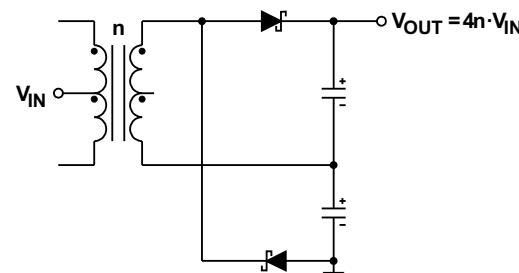
**Figure 69. Bridge Rectifier with Center-Tapped Secondary Enables Bipolar Outputs**



**Figure 70. Bridge Rectifier Without Center-Tapped Secondary Performs Voltage Doubling**



**Figure 71. Half-wave Rectifier Without Center-tapped Secondary Performs Voltage Doubling, Centered Ground provides Bipolar Outputs**



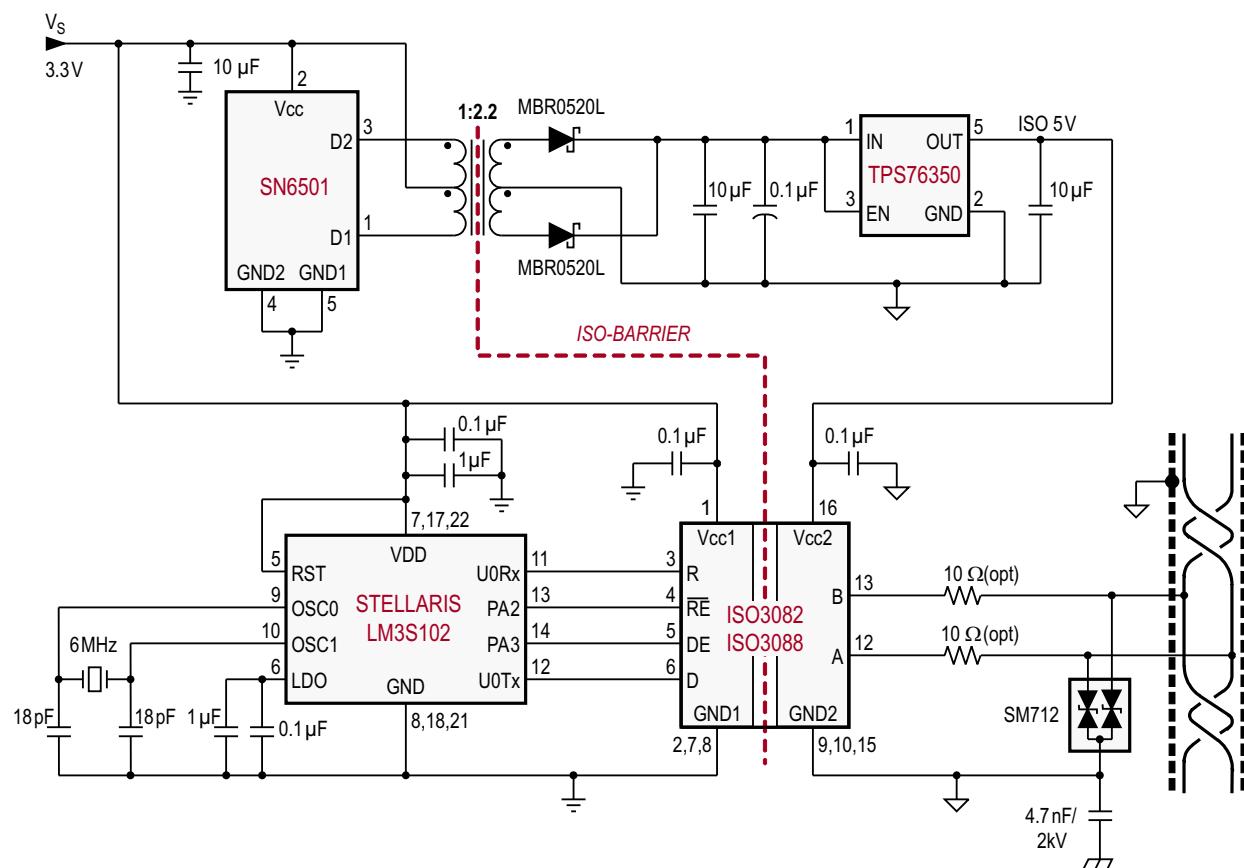
**Figure 72. Half-wave Rectifier Without Centered Ground and Center-tapped Secondary Performs Voltage Doubling Twice, Hence Quadrupling V<sub>IN</sub>**

## APPLICATION CIRCUITS

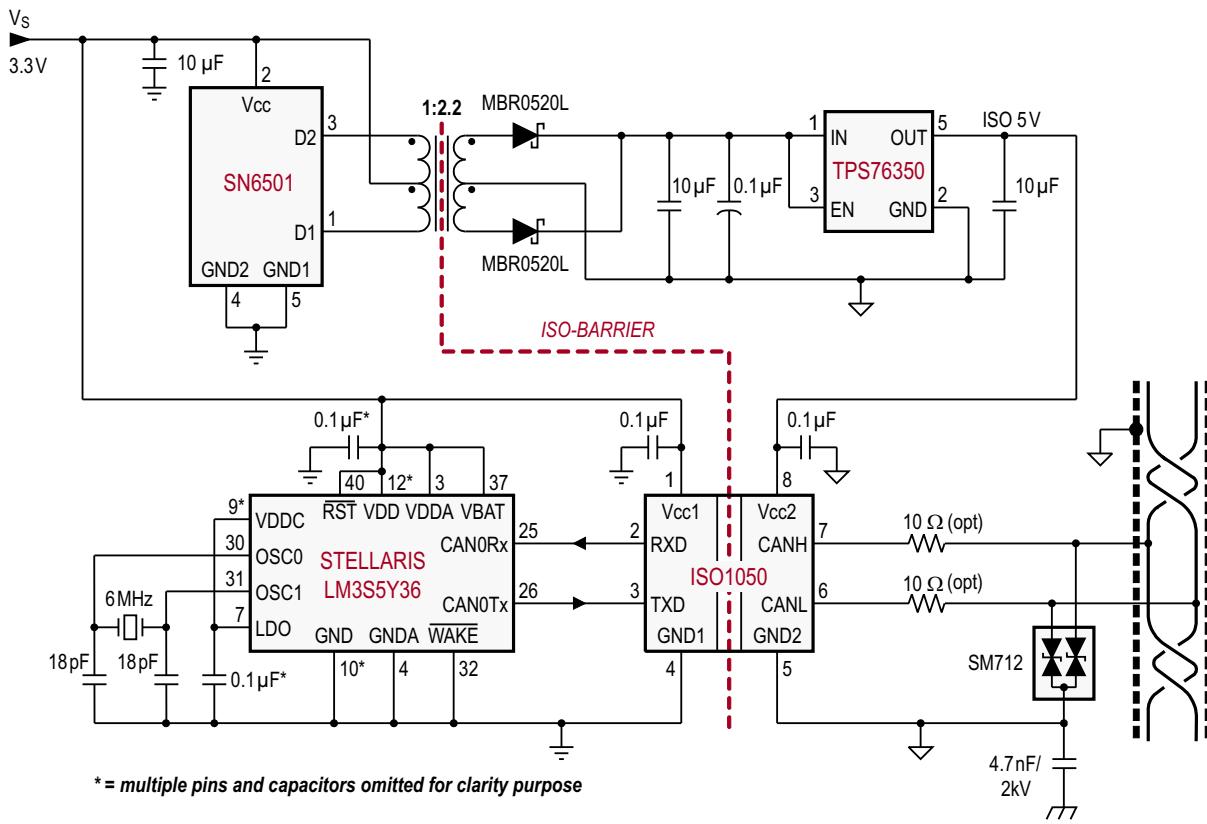
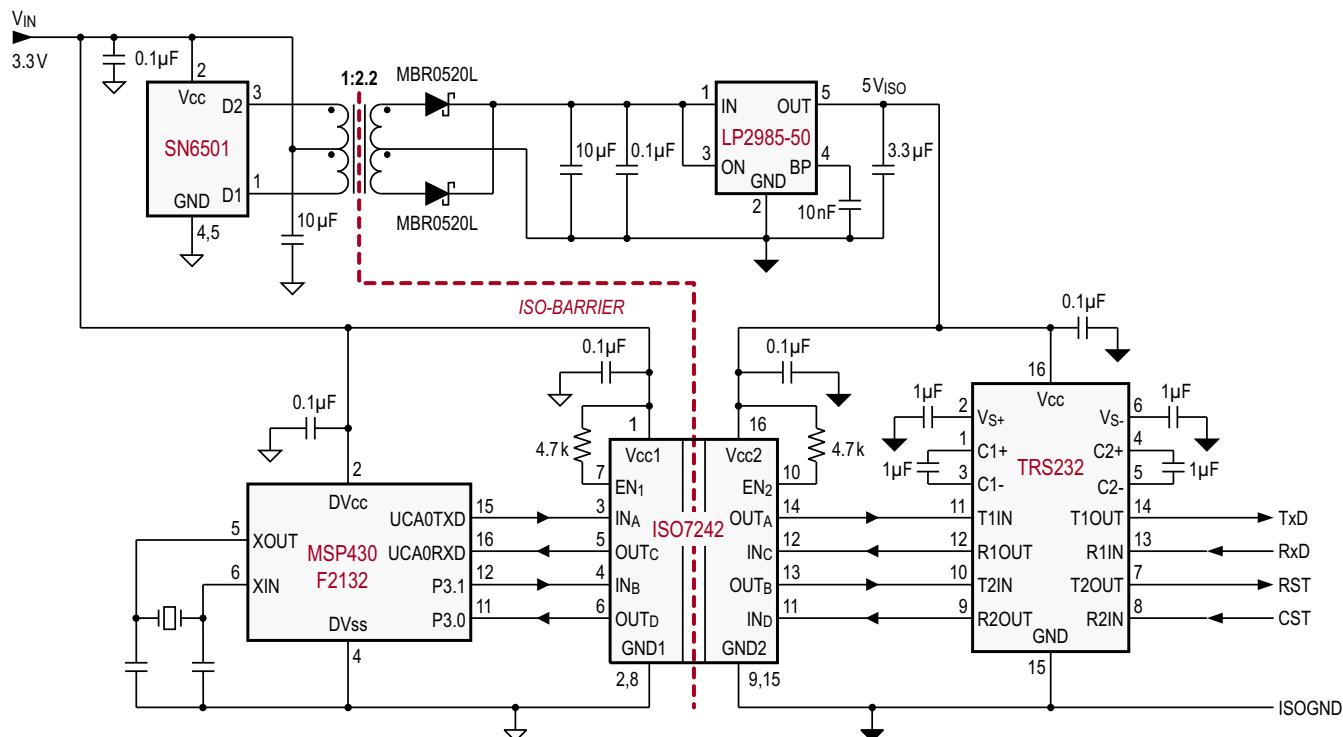
The following application circuits are shown for a 3.3 V input supply commonly taken from the local, regulated micro-controller supply. For 5 V input voltages requiring different turn ratios refer to the transformer manufacturers and their websites listed in Table 4.

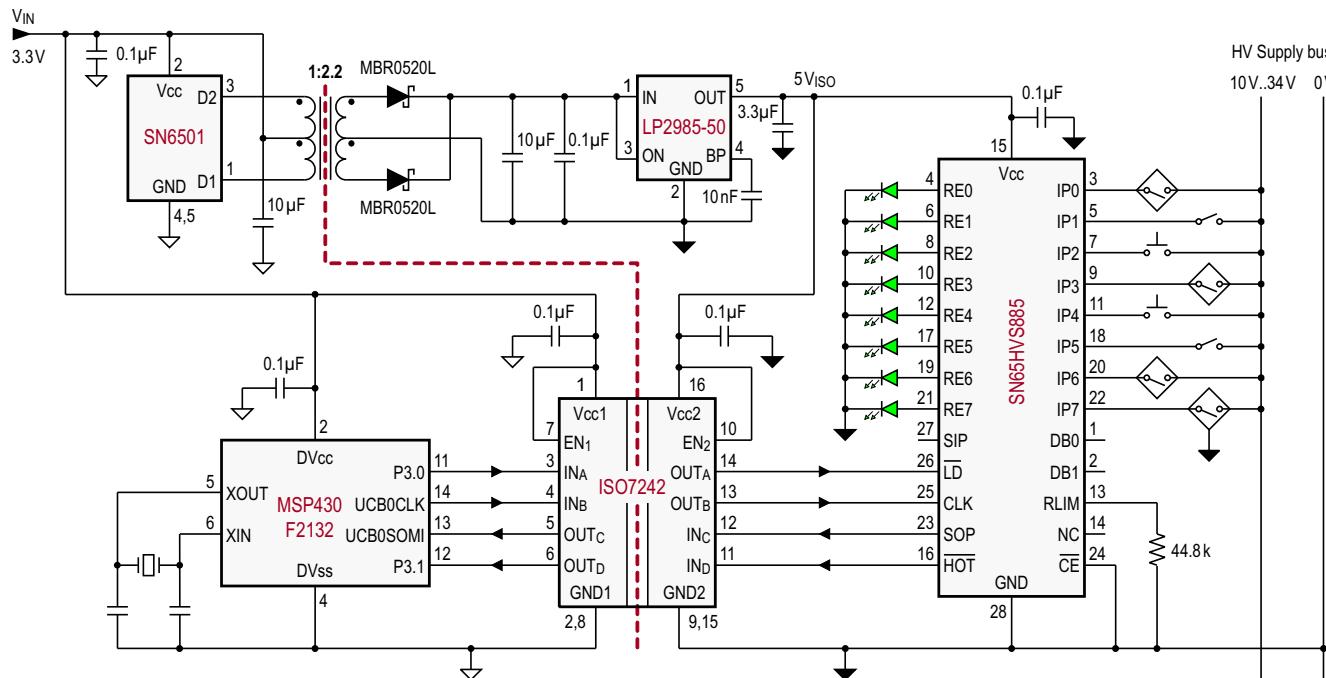
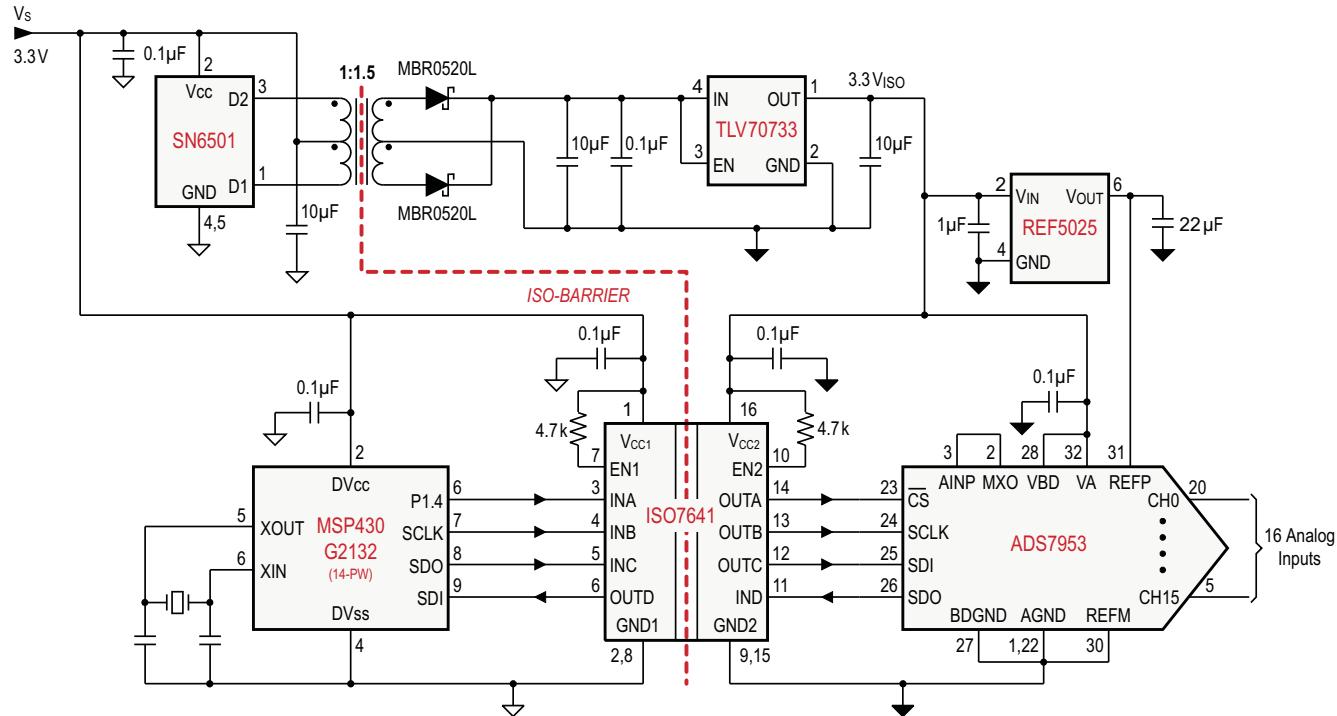
**Table 4. Transformer Manufacturers**

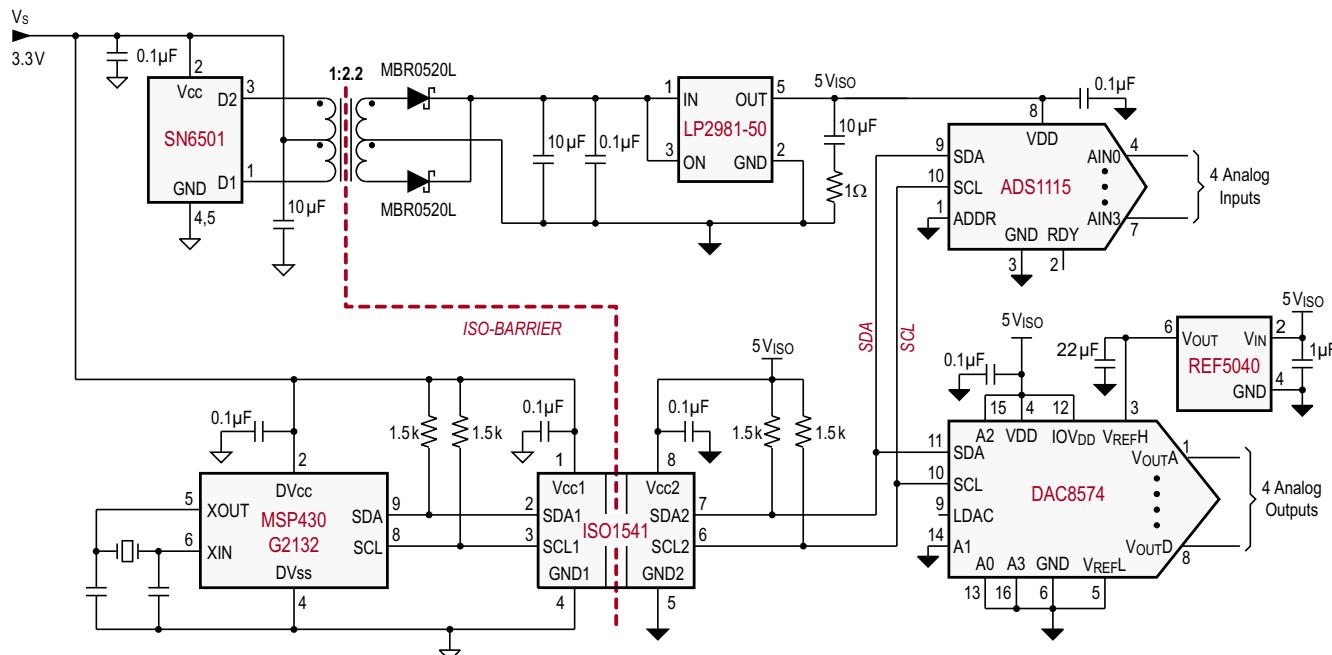
Coilcraft Inc.	<a href="http://www.coilcraft.com">http://www.coilcraft.com</a>
Halo-Electronics Inc.	<a href="http://www.haloelectronics.com">http://www.haloelectronics.com</a>
Murata Power Solutions	<a href="http://www.murata-ps.com">http://www.murata-ps.com</a>
Wurth Electronics Midcom Inc	<a href="http://www.midcom-inc.com">http://www.midcom-inc.com</a>



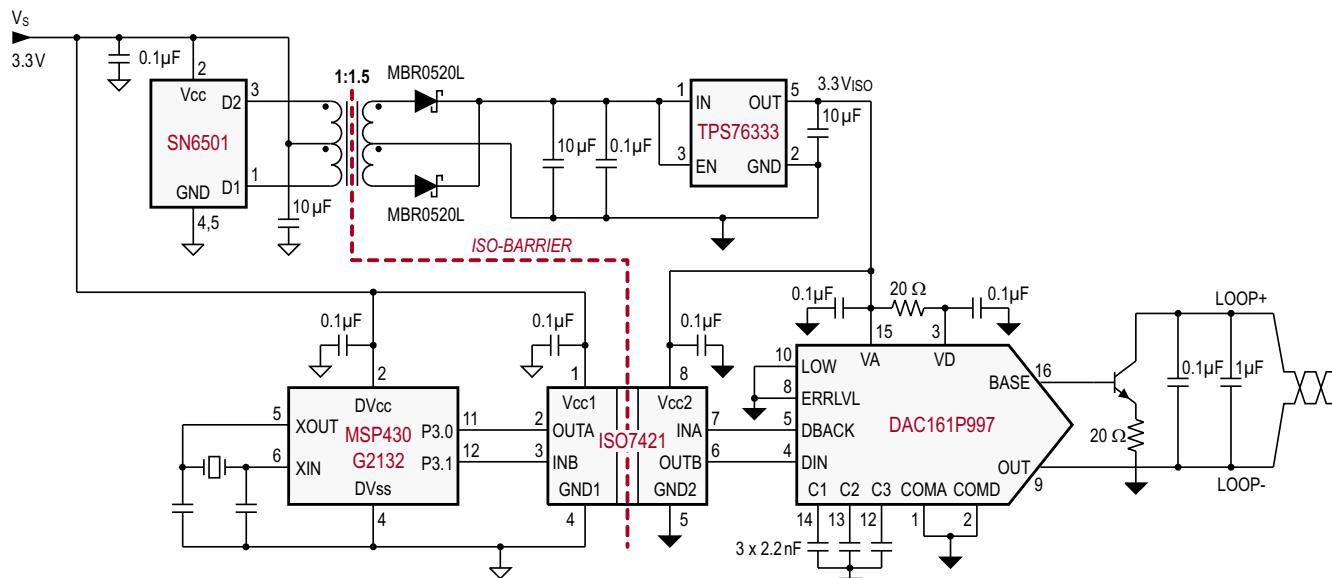
**Figure 73. Isolated RS-485 Interface**


**Figure 74. Isolated CAN Interface**

**Figure 75. Isolated RS-232 Interface**


**Figure 76. Isolated Digital Input Module**

**Figure 77. Isolated SPI Interface for an Analog Input Module with 16 Inputs**



**Figure 78. Isolated I2C Interface for an Analog Data Acquisition System with 4 Inputs and 4 Outputs**



**Figure 79. Isolated 4-20mA Current Loop**

## REVISION HISTORY

Changes from Original (February 2012) to Revision A	Page
• Changed the device From: Product Preview To: Production .....	1
• Added <a href="#">Figure 31</a> through <a href="#">Figure 34</a> .....	9
• Changed <a href="#">Equation 8</a> .....	20
• Changed <a href="#">Equation 9</a> .....	20
• Changed <a href="#">Table 4</a> , From: Wuerth-Elektronik / Midcom To: Wurth Electronics Midcom Inc .....	22
• Changed <a href="#">Figure 77</a> .....	25

Changes from Revision A (March 2012) to Revision B	Page
• Changed Feature From: Small 5-pin DBV Package To: Small 5-pin SOT23 Package .....	1
• Changed <a href="#">Figure 68</a> title .....	20

Changes from Revision B (March 2012) to Revision C	Page
• Changed the $f_{osc}$ Oscillator frequency values .....	4
• Changed <a href="#">Equation 2</a> .....	19

Changes from Revision C (March 2012) to Revision D	Page
• Changed $f_{osc}$ , Oscillator frequency To: $f_{sw}$ , D1, D2 Switching frequency .....	4
• Added graphs <a href="#">Figure 3</a> through <a href="#">Figure 8</a> .....	5
• Added <a href="#">Figure 51</a> through <a href="#">Figure 54</a> .....	12
• Changed the title of <a href="#">Figure 56</a> From: D1, D2 Oscillator Frequency vs Free-Air Temperature To: D1, D2 Switching Frequency vs Free-Air Temperature .....	13
• Added section: Recommended Transformers .....	20
• Changed the location and title of <a href="#">Figure 68</a> .....	20

Changes from Revision D (September 2012) to Revision E	Page
• Changed <a href="#">Figure 22</a> .....	7

Changes from Revision E (January 2013) to Revision F	Page
• Added <a href="#">Figure 9</a> through <a href="#">Figure 14</a> .....	5
• Added <a href="#">Figure 19</a> and <a href="#">Figure 20</a> .....	7
• Added <a href="#">Figure 23</a> through <a href="#">Figure 30</a> .....	8
• Changed <a href="#">Table 2</a> - Recommended Isolation Transformers Optimized for SN6501 .....	21

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN6501DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	6501	<b>Samples</b>
SN6501DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	6501	<b>Samples</b>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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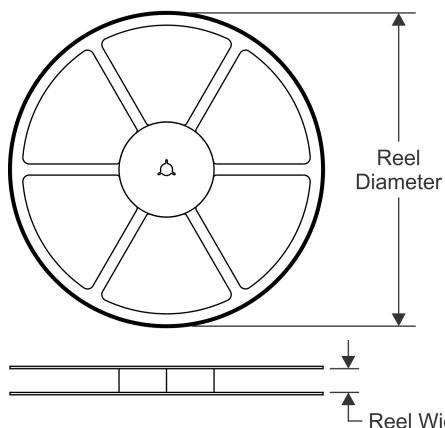
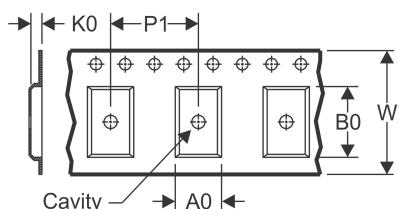
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OTHER QUALIFIED VERSIONS OF SN6501 :

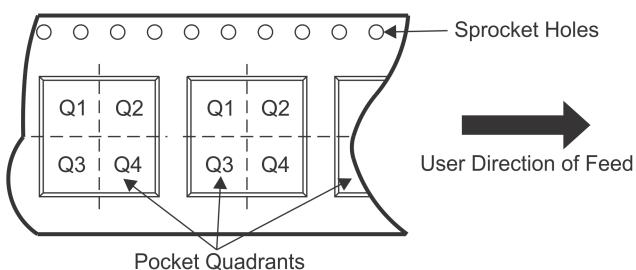
- Automotive: [SN6501-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

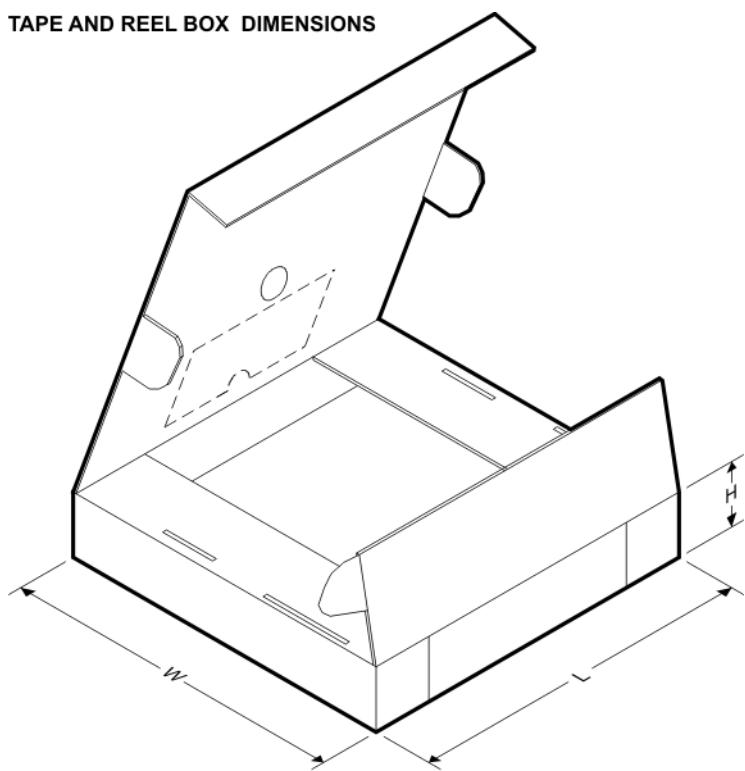
**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

**TAPE DIMENSIONS**


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN6501DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN6501DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

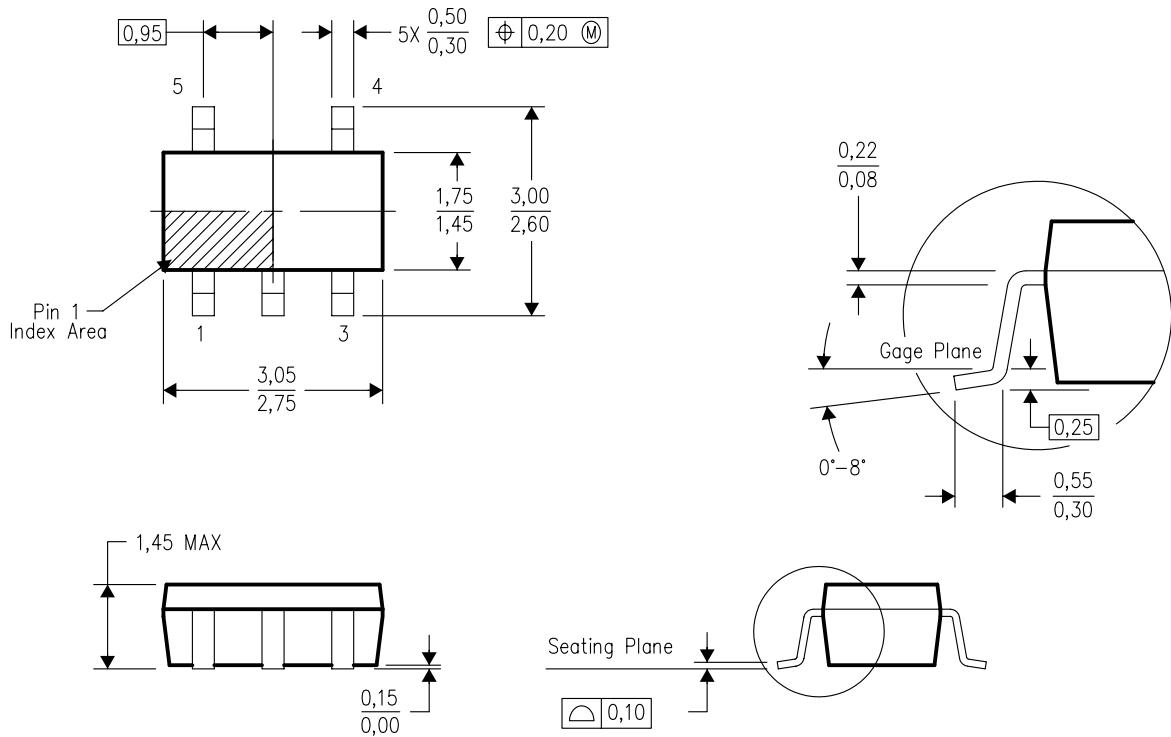
**TAPE AND REEL BOX DIMENSIONS**

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN6501DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN6501DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0

## DBV (R-PDSO-G5)

## PLASTIC SMALL-OUTLINE PACKAGE



4073253-4/K 03/2006

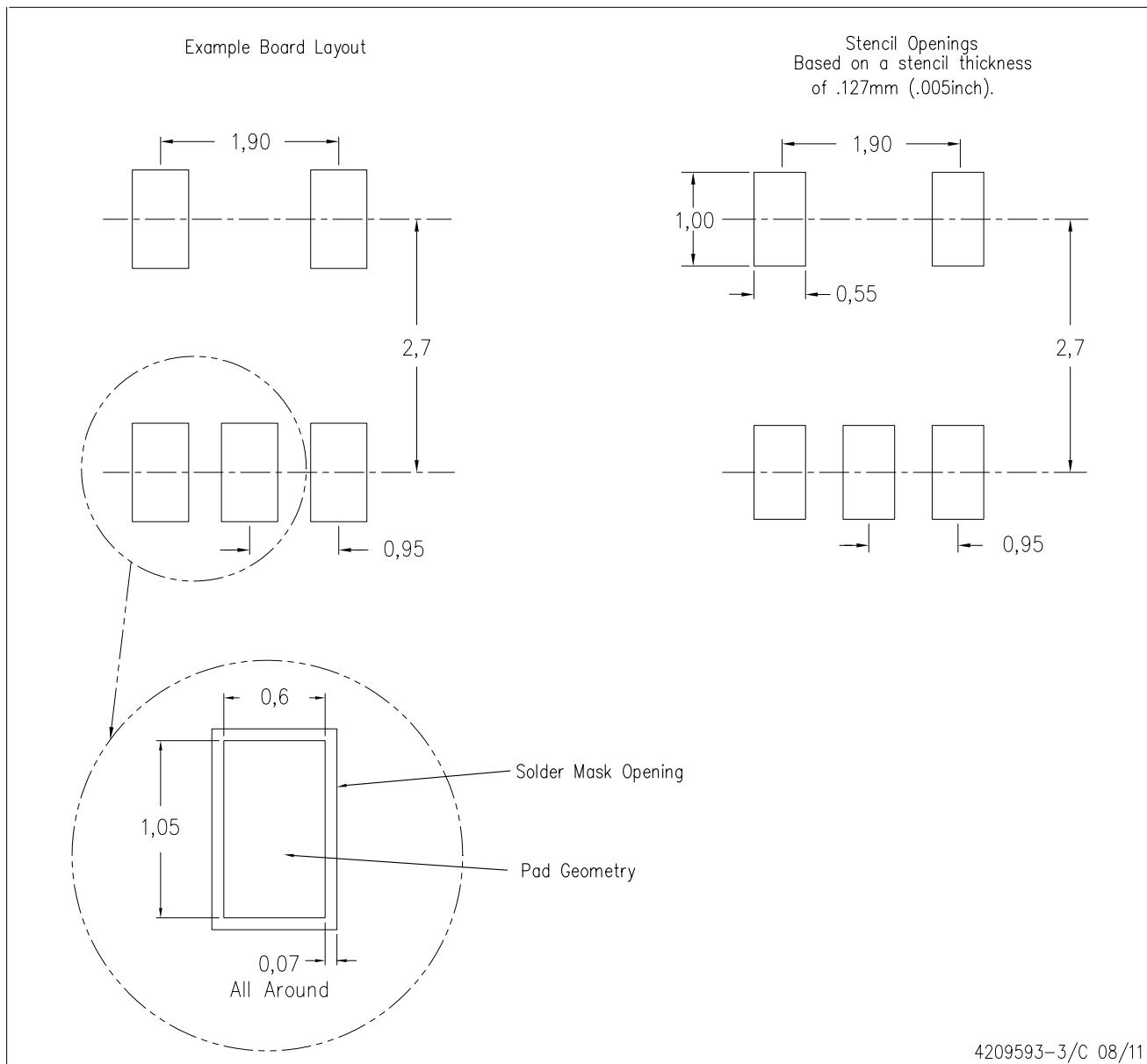
NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- Falls within JEDEC MO-178 Variation AA.

## LAND PATTERN DATA

DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

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DLP® Products	<a href="http://www.dlp.com">www.dlp.com</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>
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